

# Simulation and theory on magnetism

## Part 2

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# Outline (Part 2)

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1. Spin-orbit coupling origin
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2. Rashbaness of FM/HM bilayers
  1. Orbital moment
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3. Interfacial magnetic properties
  1. Interfacial or surface magnetocrystalline anisotropy energy
  2. Interfacial Dzyaloshinskii-Moriya interaction & Chiral Damping
  3. Angular dependence of spin-orbit torque (SOT)

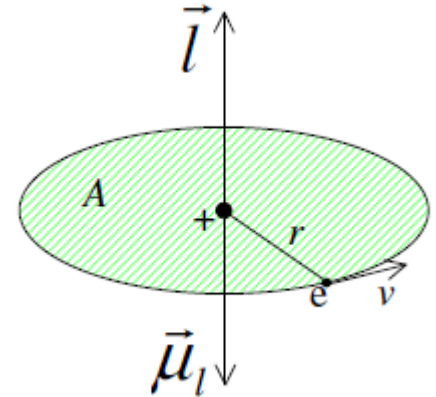
# **1. Spin-orbit coupling origin**

# Spin-orbit coupling

- The electron
  - Spin (angular momentum)  $s$  ( $\sim$  self-rotation of electron)
  - Orbital angular momentum  $l$  ( $\sim$  rotation of electron around nuclei)
- For each angular momentum, there is an associated magnetic moment,  $\mu_l$  and  $\mu_s$
- Spin-orbit coupling (SOC) = Interaction between these two magnetic moments

# Orbital magnetic moment $\mu_l$

- Electron orbit  $\rightarrow$  current  $\rightarrow$  magnetic moment
- $\mu_l = (\text{current}) \times (\text{area of the loop}) = I A$
- Orbit period =  $T = 2\pi/\omega$
- $I = (\text{charge})/(\text{Time}) = -e/T = -e\omega/(2\pi)$
- $\mu_l = I A = -e\omega/(2\pi) \times (\pi r^2) = -e \omega r^2/2$
- Angular momentum  $|\mathbf{l}| = |\mathbf{r} \times \mathbf{p}| = m_0 v r = m_0 \omega r^2$
- $\rightarrow \mu_l = -e/(2 m_0) l$
- Note1:  $\mu_l$  and  $l$  are in opposite direction ( $e < 0$ )
- Note2: If  $|\mathbf{l}| = h/(2\pi) = \hbar$  [ground state of Bohr model]
- $\rightarrow \mu_B = e \hbar / (2 m_0)$  : Bohr magneton = unit of magnetic moment



# Spin magnetic moment $\mu_s$

- (electron) Spin = intrinsic angular momentum with quantum number  $s = \frac{1}{2}$
- Justified by Stern-Gerlach experiment + Dirac's relativistic theory
- $\rightarrow \mu_s = -g e/(2 m_0) s$
- $g =$  Landé  $g$ -factor = 2.002319 for an atom (usually larger than 2 in solid)
- Note1:  $g = 1$  classically (Bohr model),  $g = 2$  comes from Dirac's relativistic quantum theory
- Small corrections from quantum electrodynamics

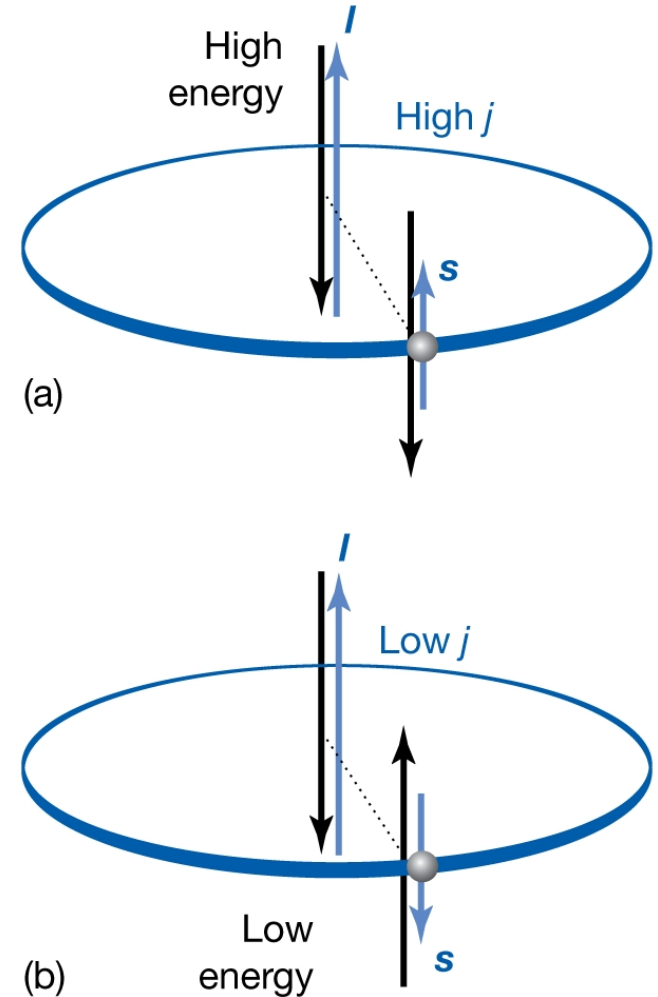
# Einstein-de-Haas effect vs Barnett effect

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- Einstein-de-Haas → current pulse in solenoid → B field → sample  
M increases → sample rotates →  $M \sim$  angular momentum
- Barnett effect → inverse effect of Einstein-de-Haas

# Magnetic energy $\rightarrow$ SOC

- From “nucleus” point-of-view = electron rotates around me and generates a magnetic field
- From “electron” point-of-view = nucleus rotates around me and generates a magnetic field = relativistic electron’s orbital motion  $\rightarrow \mathbf{B}_l$
- $E = -\boldsymbol{\mu}_s \cdot \mathbf{B}_l \rightarrow$  SOC
- Note: Also an energy for “nucleus” (because nucleus has its own spin). But it is small and contributes to hyperfine structure





# SOC in Dirac equation

- 1/c expansion of Dirac eq.

$$\hat{H} = \underbrace{\frac{\hat{p}^2}{2m}}_{\text{non-relativistic}} + eV + \underbrace{\frac{\hat{p}^4}{8m^2c^2}}_{\text{K.E. correction}} + \underbrace{\frac{\hbar^2}{8m^2c^2}\nabla^2V}_{\text{Darwin term}} + \underbrace{\frac{\hbar}{4m^2c^2}\vec{\sigma}\cdot(\vec{\nabla}V\times\hat{\mathbf{p}})}_{\text{SOI}}$$

- 4<sup>th</sup> term = SOC :  $\sigma$  = spin,  $V$  = potential

$$U = \frac{\hbar}{4m^2c^2}\vec{\sigma}\cdot(\nabla V\times\mathbf{p})$$


$$\nabla V = \frac{\mathbf{r}}{r}\frac{dV}{dr}$$

$$U = \frac{\hbar}{4m^2c^2}\frac{1}{r}\frac{dV}{dr}\vec{\sigma}\cdot(\mathbf{r}\times\mathbf{p}) = \frac{\hbar}{4m^2c^2}\frac{1}{r}\frac{dV}{dr}\vec{\sigma}\cdot\mathbf{L}$$

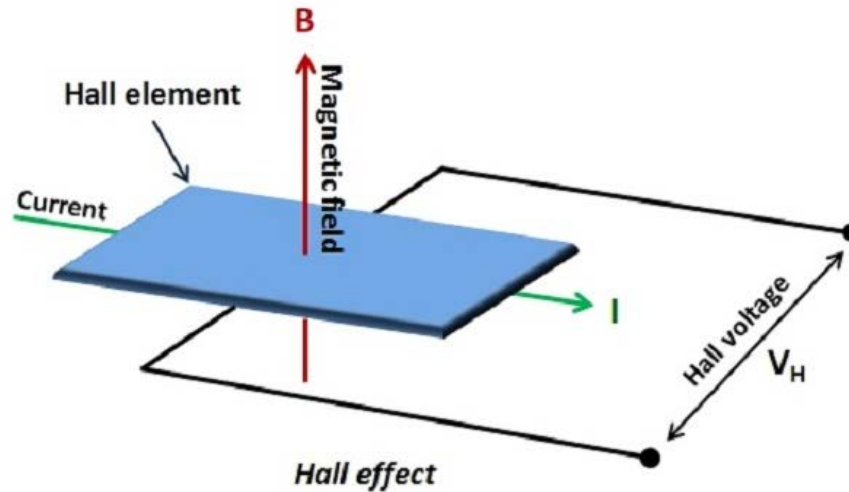
When an electron passes ( $\mathbf{p}$ ) through the region having potential gradient (= E field), its spin ( $\sigma$ ) experiences an effective magnetic field ( $\sim \mathbf{E}\times\mathbf{p}$ ).

# Why SOC?

- Electron spin passing through E field feels an effective magnetic field == SOC
- Electron spin rotates around the magnetic field and then is aligned
  - ➔ Spin(-polarized) current
- Spintronics ➔ Do something with spin current
- How to generate spin current = effective magnetic field
  - True magnetic field (but require huge one)
  - Passing through a magnet (exchange field  $\gg 10$  T)
  - Use SOC (even without FM) ➔ spin Hall effect
- What we can do with spin current
  - Spin transfer torque ➔ manipulation of local magnetization
  - Spin current  $\leftrightarrow$  Charge current conversion by SOC  $\leftarrow$  Onsager reciprocity ➔ Spin Hall effect and Inverse spin Hall effect

# Spin Hall effect (SHE)

- Charge current ( $J_e$ ) is converted to spin current ( $J_s$ ) by SOC ~ spin version of the Hall effect



$$\mathbf{V}_H = R_H \mathbf{B} \times \mathbf{J}_e \Leftrightarrow \mathbf{J}_S = \theta_{SH} \boldsymbol{\sigma} \times \mathbf{J}_e$$

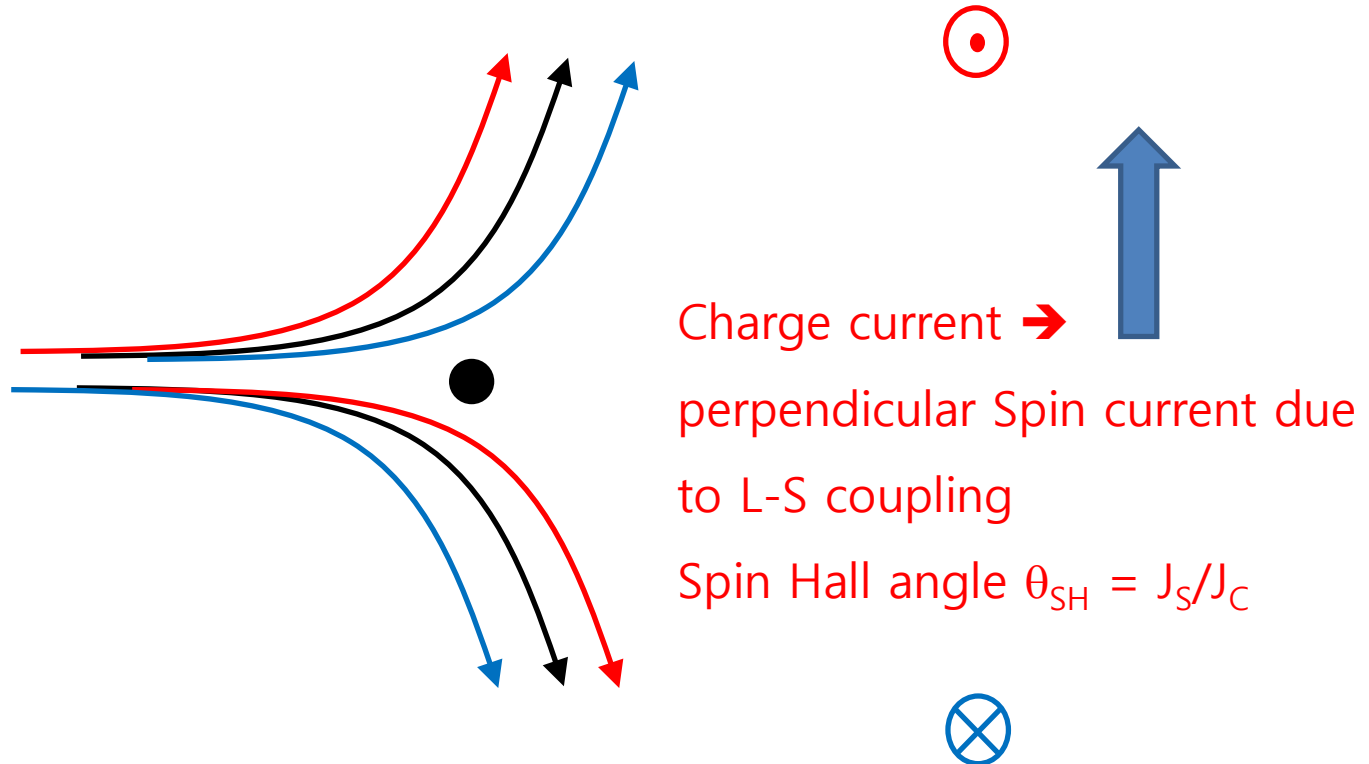
# A simple picture of SHE

- Repulsive scatterer  $V(r)$  [ $dV/dr < 0$ ]
  - Total scattering potential

$$V_{\text{eff}} = V(r) + \frac{1}{2m^2 c^2 r} \frac{dV}{dr} \mathbf{L} \cdot \mathbf{S}$$

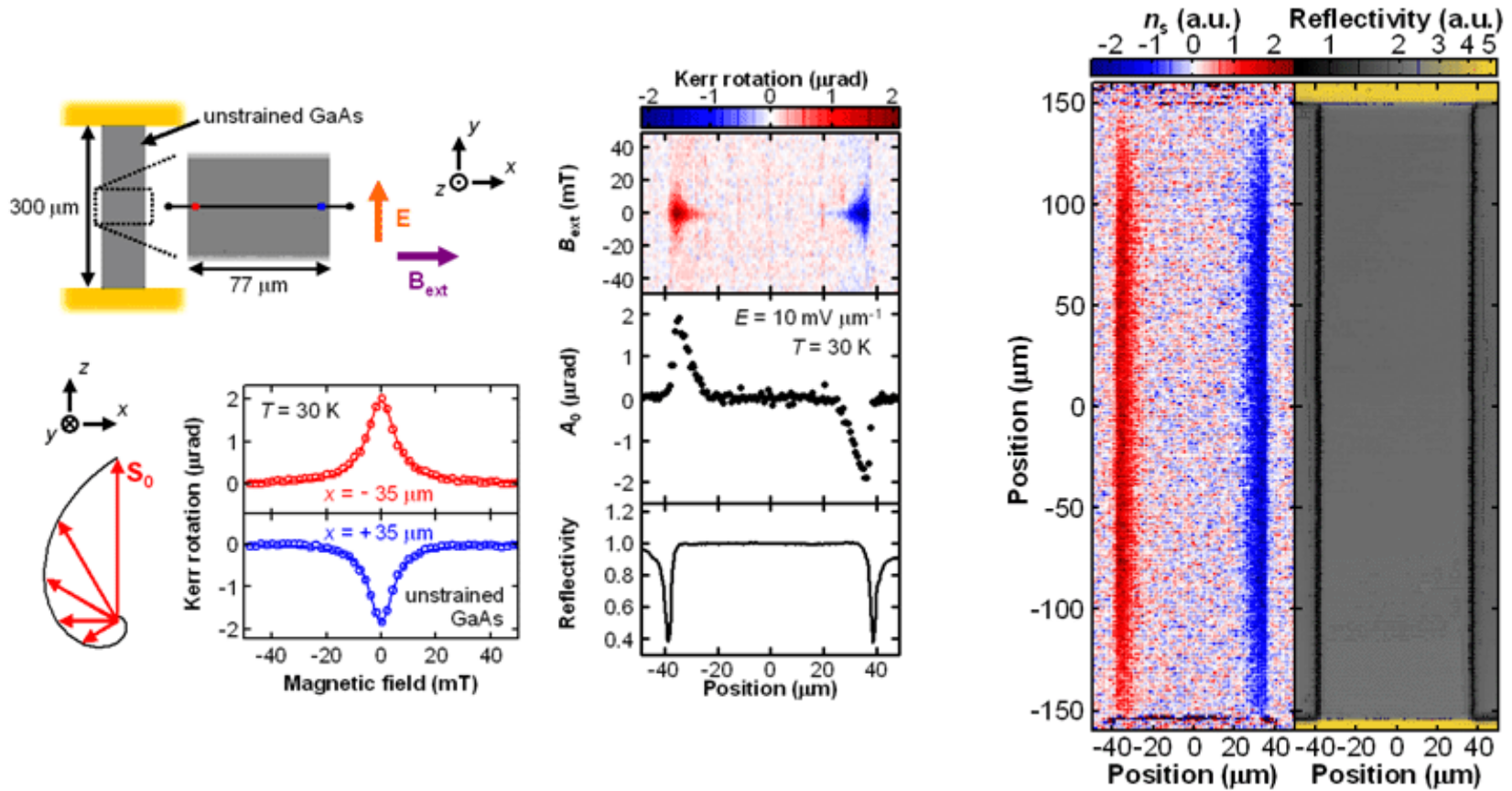
Spin Up

Spin Down



# Experiment: SHE

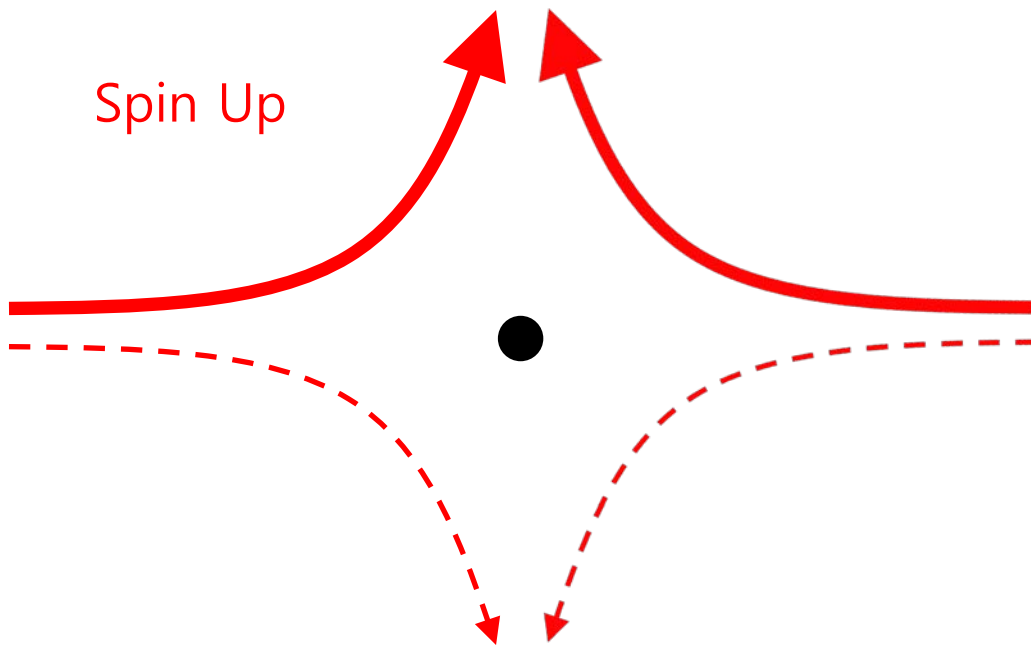
- Y. K. Kato *et al.*, Science **306**, 1910 (2004)



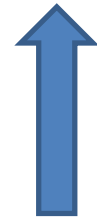
# Inverse Spin Hall effect (ISHE)

- Spin current ( $J_s$ ) is converted to charge current ( $J_e$ )

$$\mathbf{J}_e = \theta_{SH} \boldsymbol{\sigma} \times \mathbf{J}_s$$



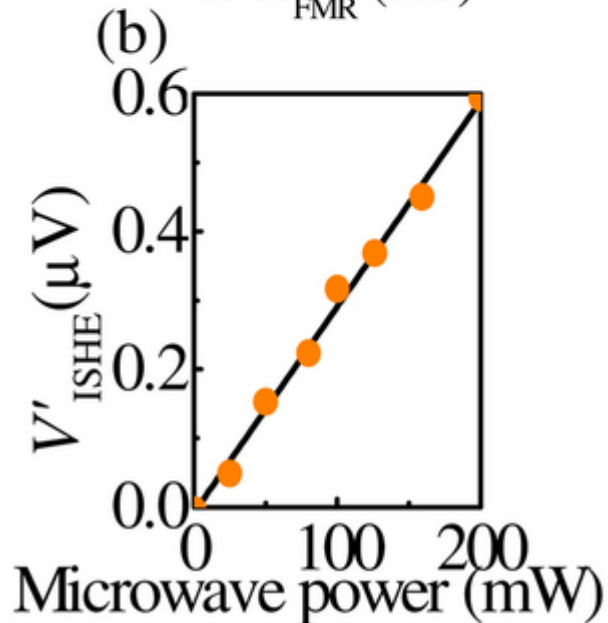
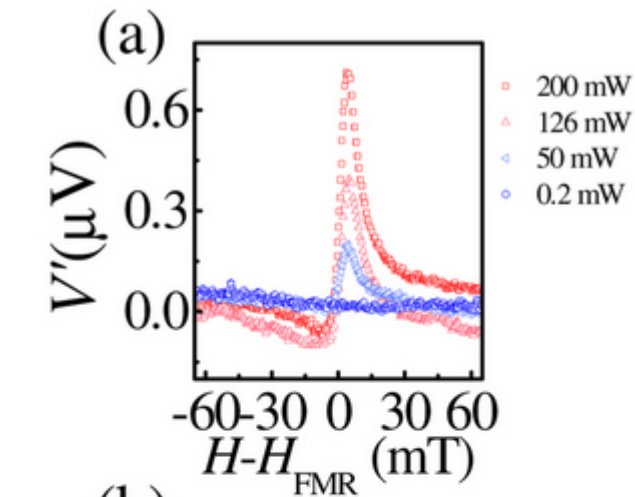
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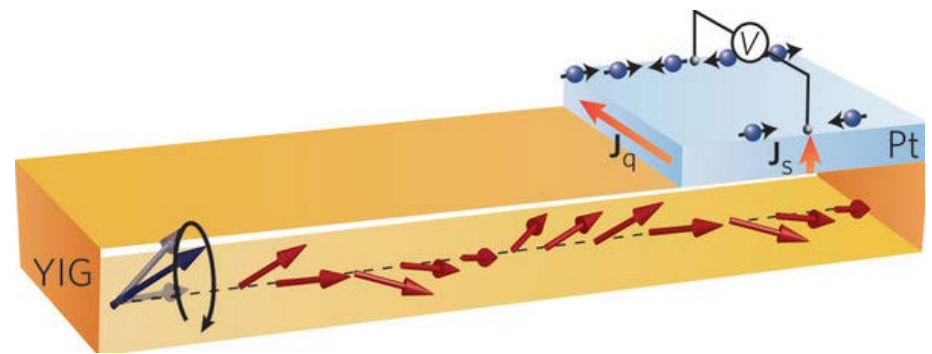
Spin current  $\rightarrow$   
perpendicular Charge  
current due to L-S coupling  
Spin Hall angle  $\theta_{SH} = J_s/J_C$

# Experiment: ISHE

- E. Saitoh *et al.*, APL **88**, 182509 (2006)



Sensing the Spin Seebeck effect



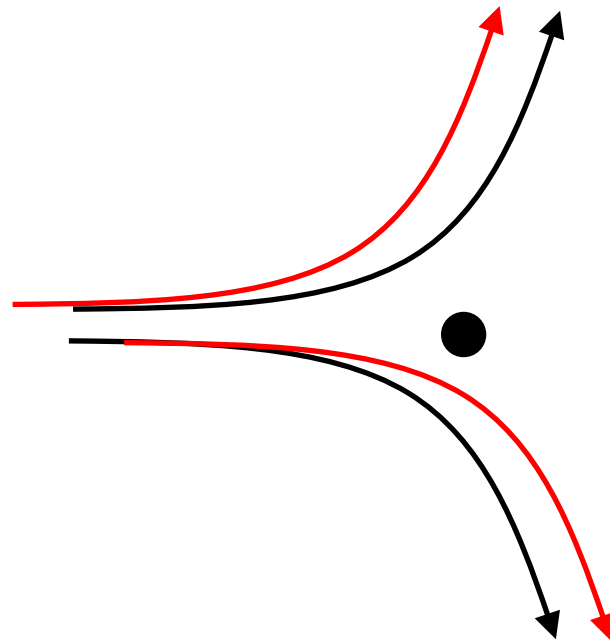
# Anomalous Hall effect (AHE)

- Repulsive scatterer  $V(r)$  [ $dV/dr < 0$ ]
  - Total scattering potential

$$V_{\text{eff}} = V(r) + \frac{1}{2m^2 c^2 r} \frac{dV}{dr} \mathbf{L} \cdot \mathbf{S}$$



Spin Up ONLY



Longitudinal charge current →  
Transverse Hall voltage  
~ SHE



# Three mechanisms of AHE

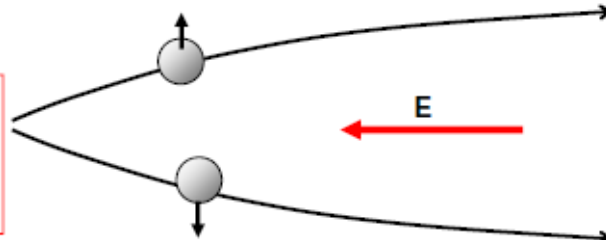
- Nagaosa et al. RMP '09

## a) Intrinsic deflection

Interband coherence induced by an external electric field gives rise to a velocity contribution perpendicular to the field direction. These currents do not sum to zero in ferromagnets.

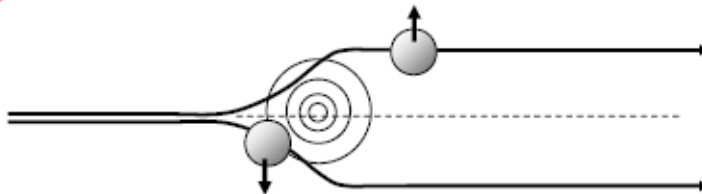
$$\frac{d\langle \vec{r} \rangle}{dt} = \frac{\partial E}{\hbar \partial \vec{k}} + \frac{e}{\hbar} \vec{E} \times \vec{b}_n$$

Electrons have an anomalous velocity perpendicular to the electric field related to their Berry's phase curvature



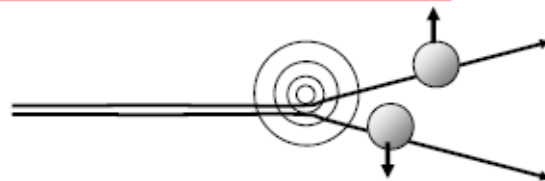
## b) Side jump

The electron velocity is deflected in opposite directions by the opposite electric fields experienced upon approaching and leaving an impurity. The time-integrated velocity deflection is the side jump.



## c) Skew scattering

Asymmetric scattering due to the effective spin-orbit coupling of the electron or the impurity.



$$\sigma_{xy} \propto \sigma_{xx}^0$$

$$\sigma_{xy} \propto \sigma_{xx}^1$$

Note 1: "Intrinsic" and "side-jump" are not easy to be separated in experiment

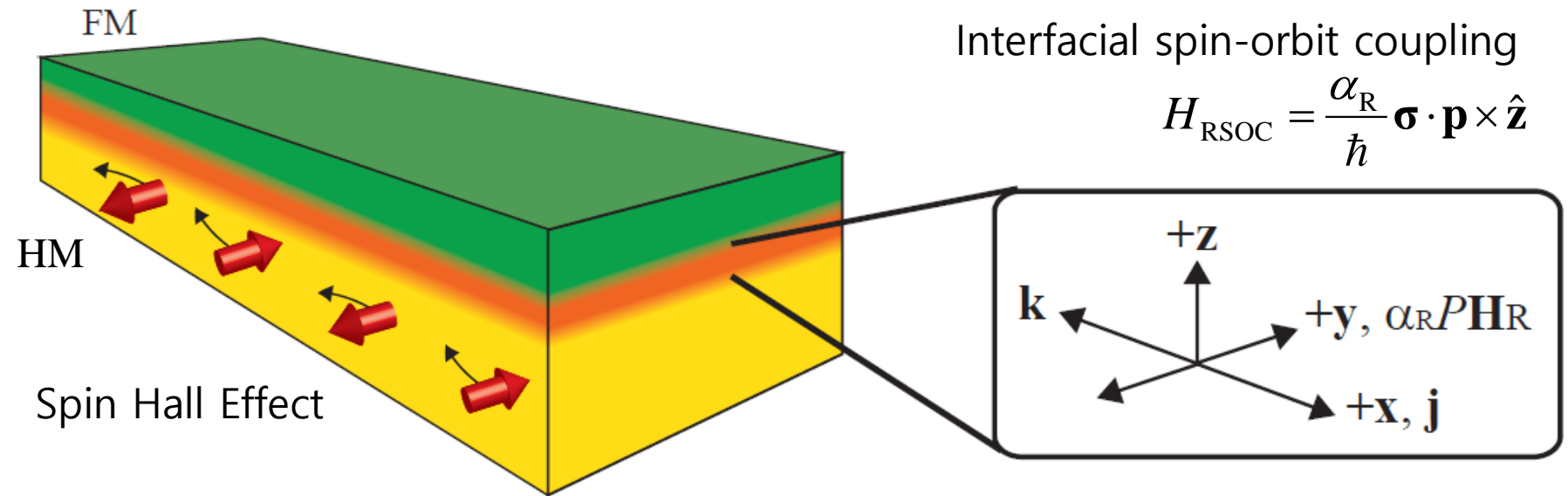
Note 2: "Skew" is dominant for very good metal.

## **2. “Rashbaness” of FM/HM bilayers**

**2-1. Orbital moment for RSOC**

**2-2. Signatures of Rashbaness in  
FM/HM bilayers**

# Ferromagnet (FM)/Heavy metal (HM) bilayer



- **Effects of Interfacial (Rashba) SOC**

- **Field-like spin torque:** Manchon & Zhang, PRB 08; Obata & Tatara, PRB 08; Matos-Abiague & Rodriguez-Suarez, PRB 09
- **Damping-like spin torque:** Wang & Manchon, PRL 12; Kim, Seo, Ryu, KJL, HWL, PRB 12; Pesin & MacDonald, PRB 12; Kurebayashi et al., Nat. Nano.

'14

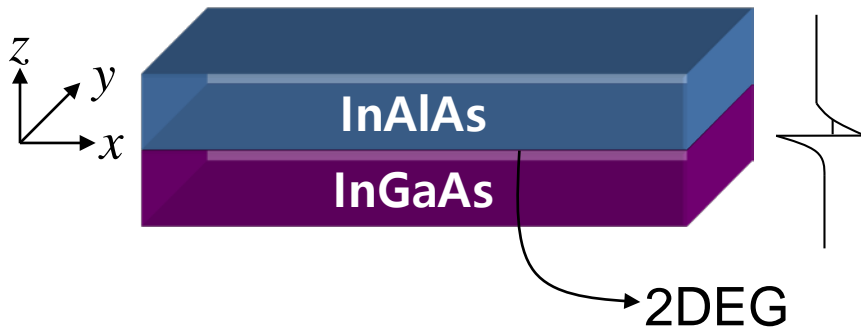
- Experiment: Miron et al., Nat. Mat. 10, 11; Nature 2012 (Pt|Co|AlOx)

# A simple picture of Rashba effect

- Relativistic correction

$$H_{\text{so}} = -\boldsymbol{\mu}_{\text{B}} \cdot \mathbf{B}_{\text{eff}} = -\frac{1}{2} \left( \frac{e\hbar}{2m} \boldsymbol{\sigma} \right) \cdot \left( -\frac{1}{c^2} \mathbf{v} \times \mathbf{E} \right) = \frac{\hbar}{4m^2 c^2} \boldsymbol{\sigma} \cdot \mathbf{p} \times \nabla V(\mathbf{r})$$

- Structural inversion asymmetry in heterostructures



$$H_{\text{R}} = \frac{\alpha_{\text{R}}}{\hbar} \boldsymbol{\sigma} \cdot (\mathbf{p} \times \hat{\mathbf{z}})$$



Let  $\mathbf{p} = \hbar k_F \hat{\mathbf{x}}$

$$H_{\text{R}} = \alpha_{\text{R}} k_F \boldsymbol{\sigma} \cdot (\hat{\mathbf{x}} \times \hat{\mathbf{z}}) = -\boldsymbol{\sigma} \cdot \alpha_{\text{R}} k_F \hat{\mathbf{y}}$$

$$\mathbf{E}_{\text{R}} = -\boldsymbol{\sigma} \cdot \mathbf{B}_{\text{eff}} \Rightarrow \mathbf{B}_{\text{eff}} \propto \alpha_{\text{R}} k_F \hat{\mathbf{y}}$$

Rashba SOC generates spin density along **y**.

# RSOC strength I

- Ast *et al.*, Phys. Rev. Lett. **98**, 186807 (2007)

- “Relativistic magnetic” field + Zeeman energy

TABLE I. Selected materials and parameters characterizing the spin splitting: Rashba energy of split states  $E_{\pm}$ , wave number offset  $k_0$

Material	$E_{\pm}$ (meV)	$k_0$ (nm <sup>-1</sup> )
InGaAs	10	0.01
Ag(111)	10	0.01
Au(111)	10	0.01
Bi(111)	10	0.01
Bi/Ag	10	0.01

## “Mysteries” of RSOC strength

- “Relativistic magnetic field + Zeeman energy” interpretation → Too small  $\alpha_R$
- Correlation between atomic SOC and  $\alpha_R$  is missing

1	1																		
2	2																		
3	3	11	3																
4	4	19	4																
5	5	37	5																
6	6	55	6																
7	7	87	7	88															
LANTHANIDE SERIES					La	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu
ACTINIDE SERIES					Ac	Th	Pa	U	Np	Pu	Am	Cm	Bk	Cf	Es	Fm	Md	No	Lr

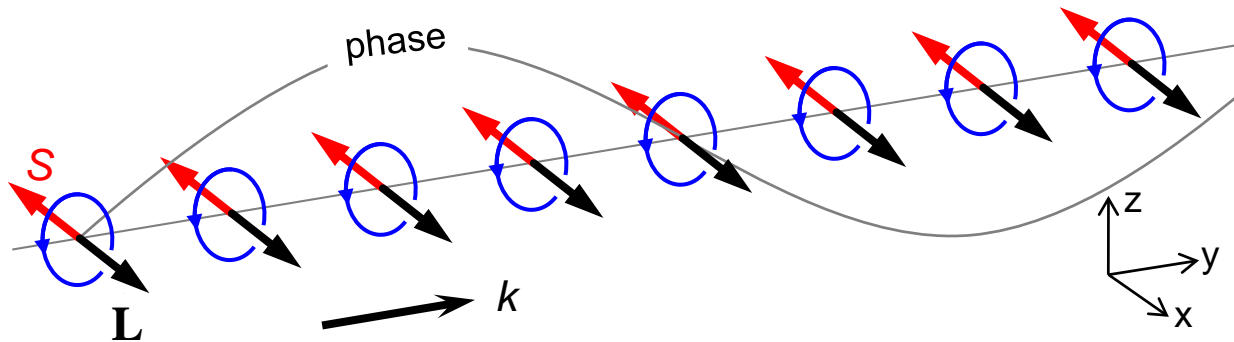
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# RSOC strength II

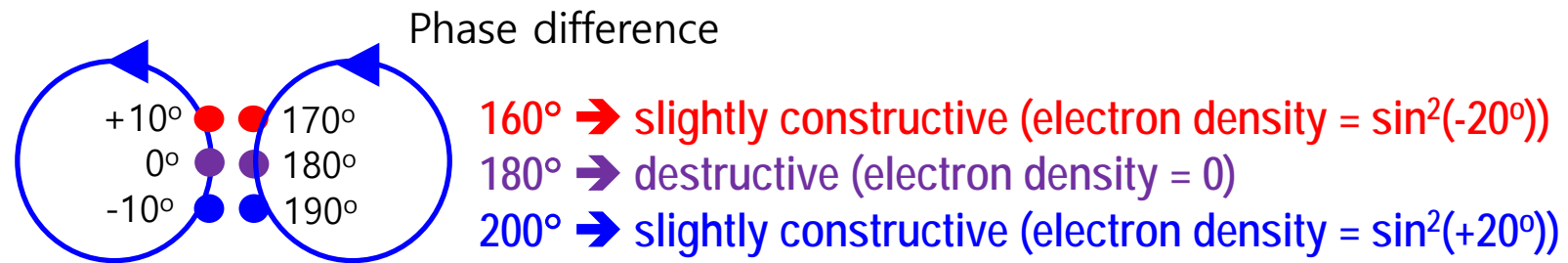
Courtesy of H.-W. Lee

S. R. Park et al., PRL 107, 156803 (2011)

- Orbital angular momentum



If NOT Bloch state

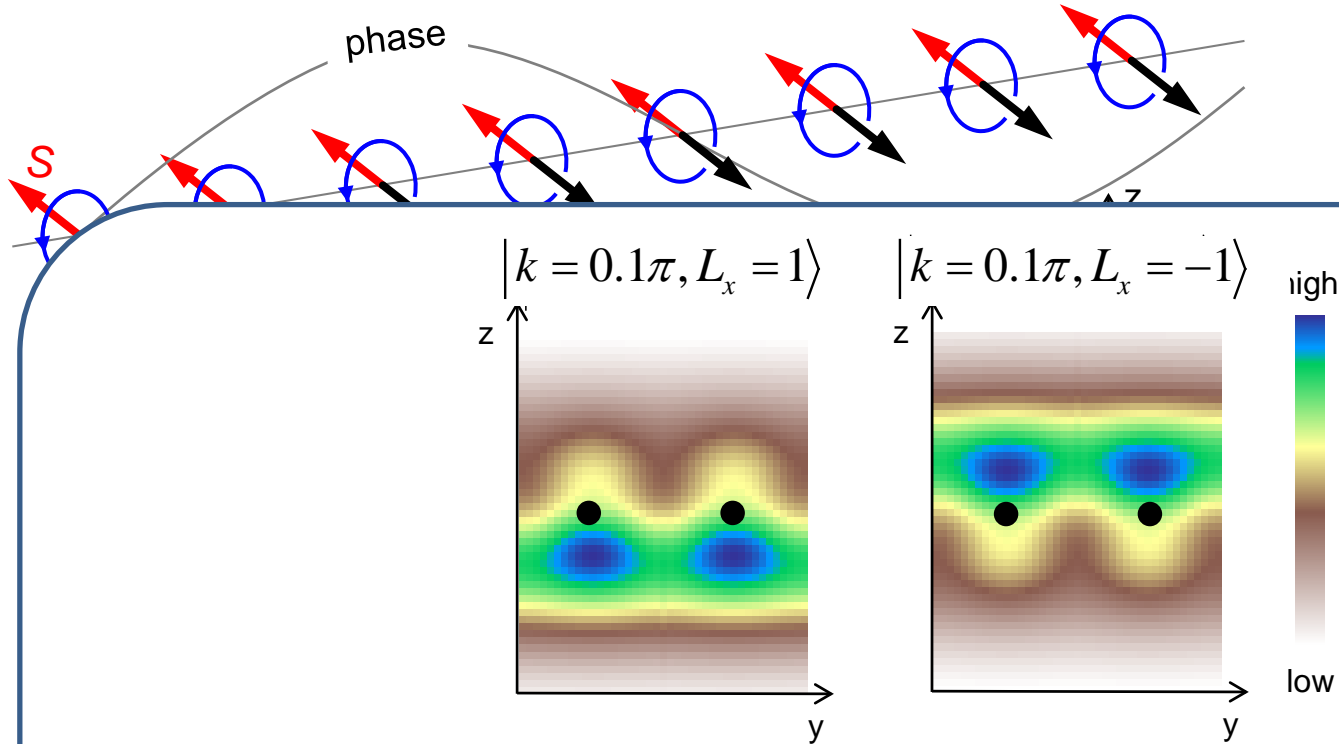


# RSOC strength II

Courtesy of H.-W. Lee

S. R. Park et al., PRL 107, 156803 (2011)

- Orbital angular momentum



$$\Delta E \propto (\mathbf{L} \times \mathbf{k}) \cdot (\text{inversion symmetry breaking vector})$$

when SOC is strong,  $\mathbf{S}$  is aligned along  $\mathbf{L} \rightarrow$

$$\propto \lambda_{\text{SOC}} (\mathbf{S} \times \mathbf{k}) \cdot (\text{inversion symmetry breaking vector})$$

# $\alpha_R$ : Magnitude estimation

“Relativistic magnetic” field  
+ Zeeman energy

$$H_{so} = \frac{\hbar}{4m^2c^2} \boldsymbol{\sigma} \times \mathbf{p} \cdot \nabla V(\mathbf{r})$$

$$H_R = \frac{\alpha_R}{\hbar} (\boldsymbol{\sigma} \times \mathbf{p}) \cdot \hat{\mathbf{z}}$$

$$\begin{aligned} \alpha_R &= \frac{1}{4} \left( \frac{\hbar}{mc} \right)^2 \langle \nabla V \rangle \\ &\sim \frac{1}{4} (\alpha a_0)^2 \frac{\text{Work function difference}}{\text{atomic spacing}} \\ &\sim \frac{1}{4} \alpha^2 \times \text{eV} \cdot \text{\AA} \sim 10^{-4} \text{ eV} \cdot \text{\AA} \end{aligned}$$

$a_0$ : Bohr radius

$\alpha$ : Fine structure constant 1/137

Orbital-induced electric dipole  
+ Atomic spin-orbit coupling

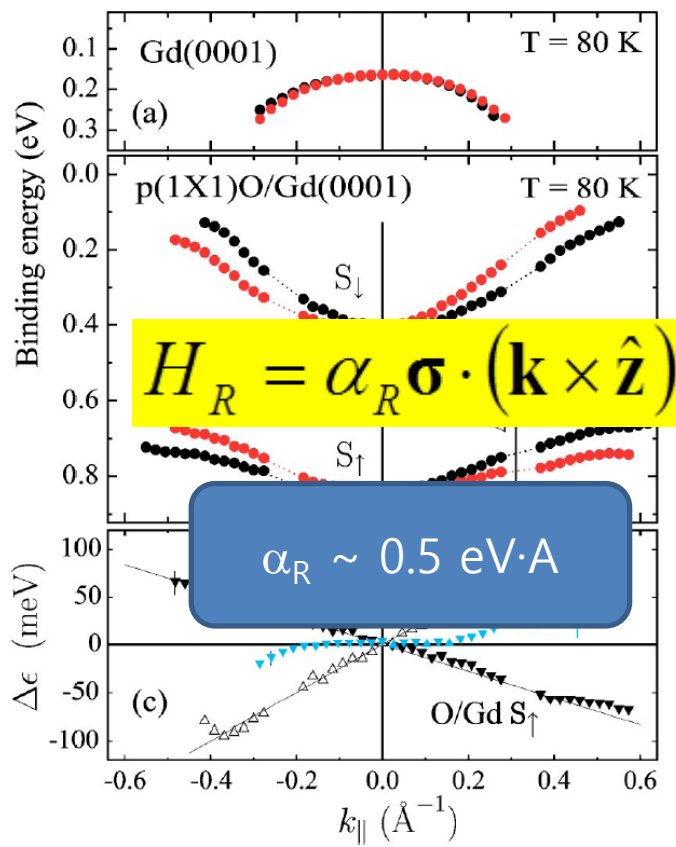
- $\Delta E \propto$  (Electric dipole energy)
  - Relevant length scale
    - $a_0, \sim \text{\AA}$
  - $\lambda_{\text{SOC}} \sim 0.1 - 1 \text{ eV}$
- $\alpha_R \sim 0.1 - 1 \text{ eV} \cdot \text{\AA}$ 
  - Similar to experimental values
  - Explains correlation with atomic number  $Z$



# Interfacial spin-orbit coupling (ISOC)

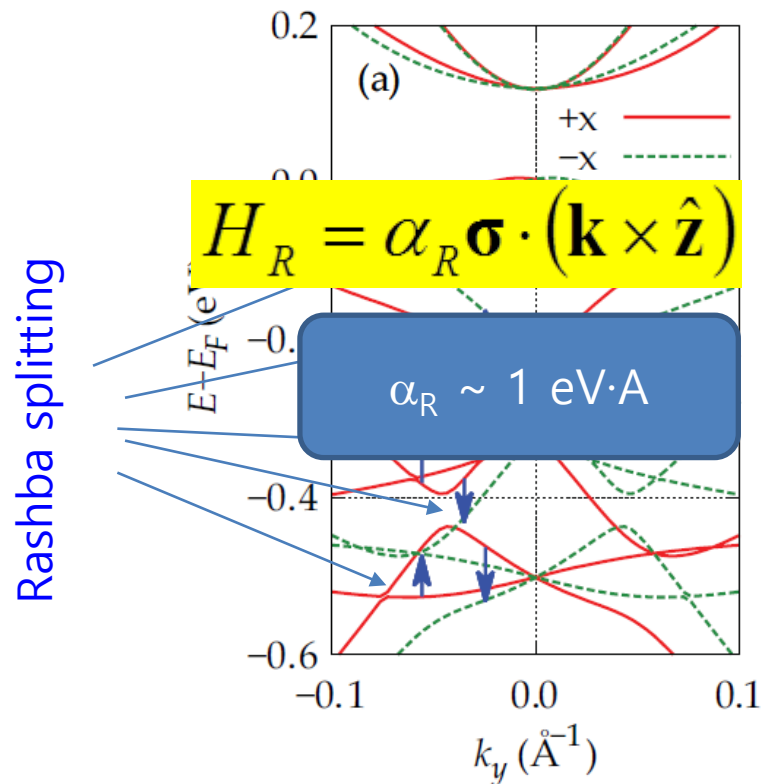
## Heavy Metal (HM) / Ferromagnet (FM) / Oxide trilayers

- Oxide/FM interface
- Gd/O; angle-resolved photoemission experiment (Krupin PRB 2005)



Rashba splitting

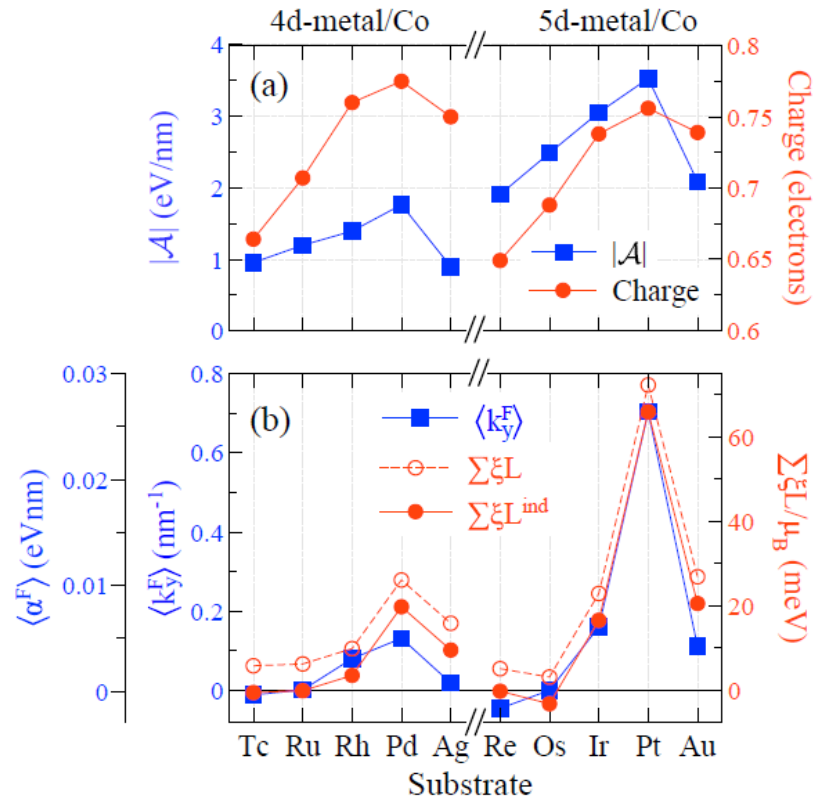
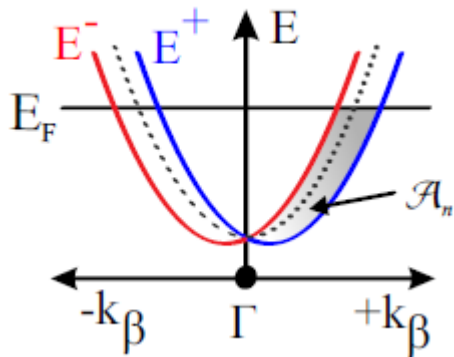
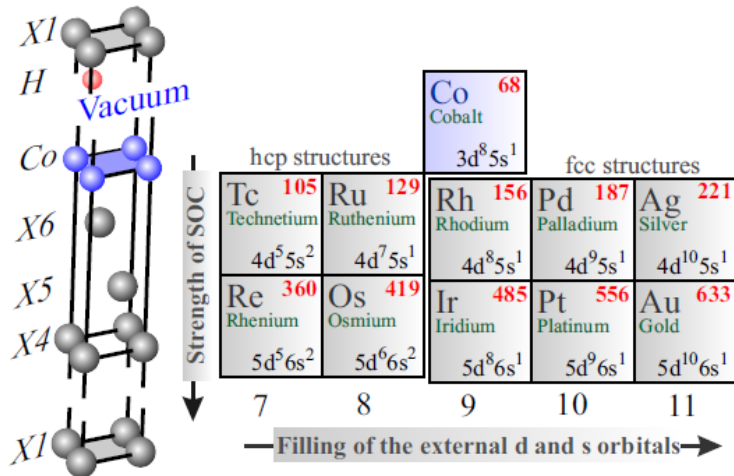
- FM/HM interface
- Co/Pt; ab initio calculation (Park PRB 2013)



Rashba splitting

# Rashbaness of various Co/HM bilayers (1)

Grytsyuk, ..., KJL, and Manchon, PRB 93, 174421 (2016)



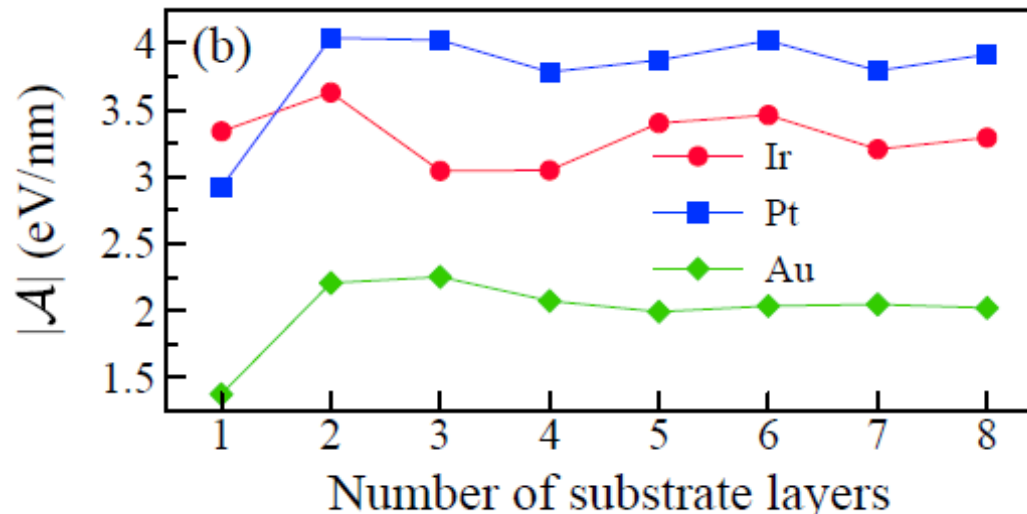
Top right = charge transfer from HM-d to Co-d  
Bottom right = induced orbital moment

All Co/HM bilayers show "Rashbaness"  $A$ .

Orbital magnetization is a measure of "Rashbaness"

# Rashbaness of various Co/HM bilayers (2)

- In FM/HM bilayers, many experimental reports find the effective spin Hall angle scales with  $\exp(-t_{\text{HM}}/\lambda_{\text{HM}})$  where  $\lambda_{\text{HM}}$  is commonly identified as spin diffusion length of HM.
- The reported spin diffusion length  $\sim 1$  nm regardless of HM (Pt, Ta, W, etc)
- The resistivity of Pt  $\ll$  resistivity of Ta or W  $\rightarrow$  very different m.f.p.
- Spin diffusion length  $\sim (\text{m.f.p.})^{1/2}$



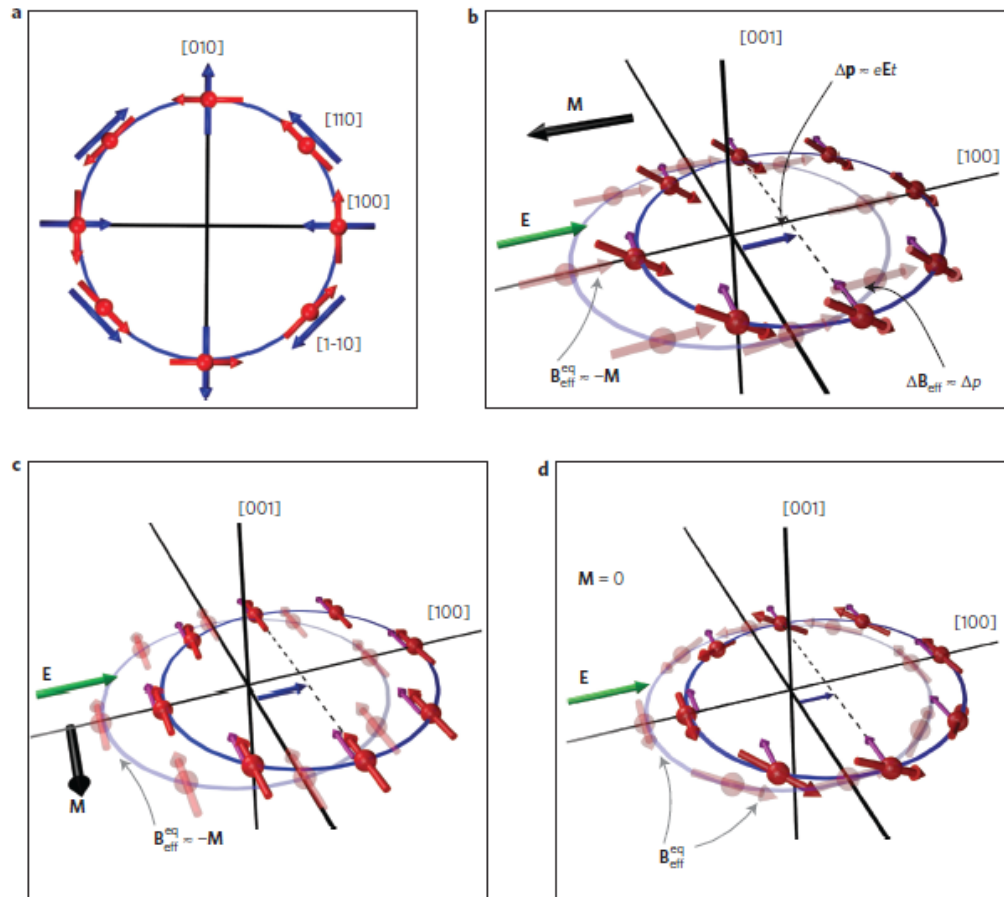
The "Rashbaness"  $A$  saturates in 2~3 monolayers of HM  $\sim 1$  nm

# Damping-like SOT from Berry curvature

Kurebyayshi et al. Nat Nano '13

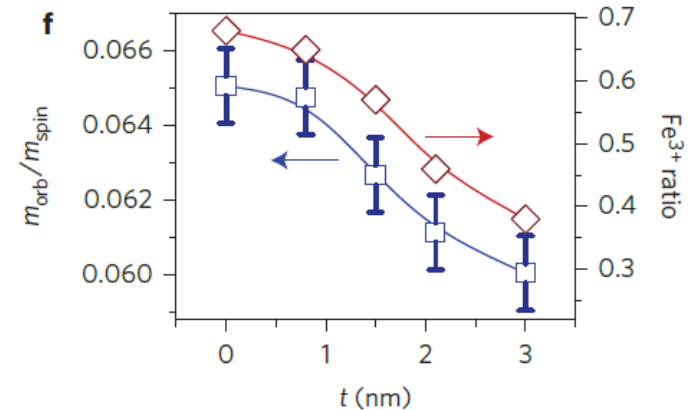
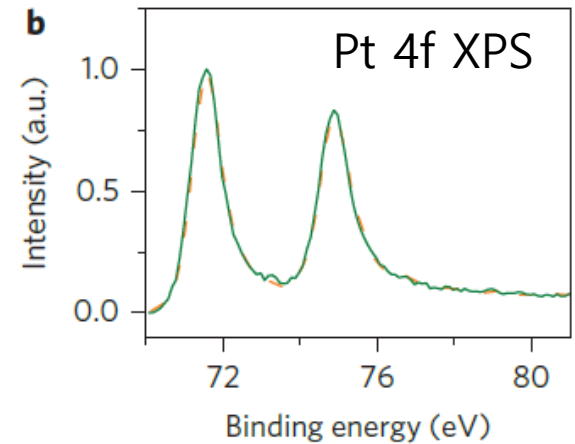
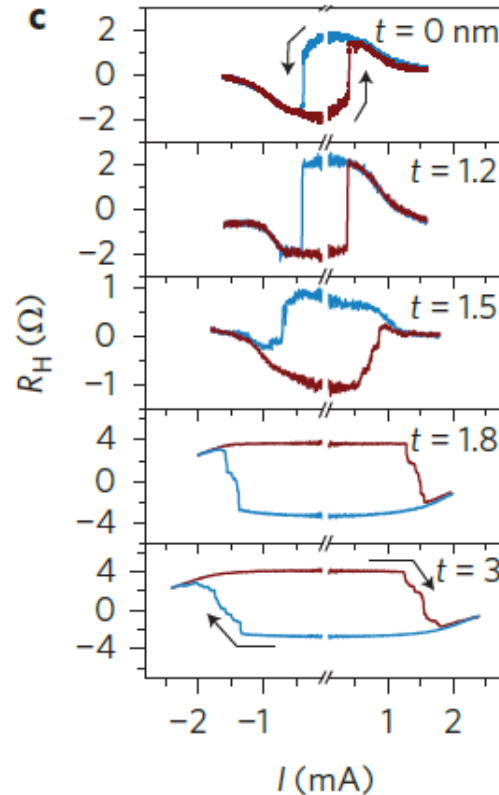
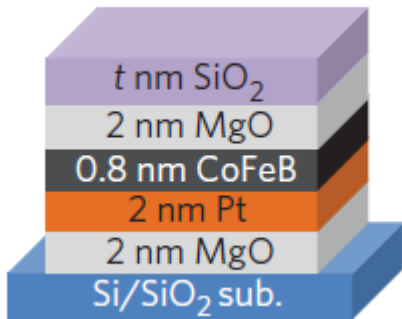
- (Ga, Mn)As  $\rightarrow$  no HM  $\rightarrow$  no bulk spin Hall effect
- Well-known band structure  $\rightarrow$  Rashba SOC
- Damping-like SOT  $\sim$  Field-like SOT  $\rightarrow$  Both SOT components well described by Rashba model

Rashba model



# SOT engineering via oxygen manipulation

Qiu, ..., KJL, Yang, Nat Nano '15



- $\text{SiO}_2$  thickness controls the oxidation of  $\text{CoFeB}$  layer  $\rightarrow$  Change in the sign of damping-like SOT (note:  $\text{Pt}$  is not oxidized)
- Close correlation with the orbital moment

## **3. Interfacial magnetic properties**

**3-1. Magnetocrystalline anisotropy energy**

**3-2. Chiral derivative → Interfacial DMI and  
Chiral damping**

**3-3. Angular dependence of SOT**

# MagnetoCrystalline Anisotropy Energy (MCA)

- Bruno model (PRB 39, 865 (1989)) → MCA ~ orbital magnetic moment anisotropy

$$MCA \sim \mu_L^\perp - \mu_L^\parallel$$

$$H = \frac{\hbar^2 k^2}{2m} + J_{sd} \boldsymbol{\sigma} \cdot \mathbf{m} + \alpha_R \boldsymbol{\sigma} \cdot (\mathbf{k} \times \mathbf{z}) \quad \& \quad \mathbf{m} = (m_x, 0, m_z)$$

$$E_k^\pm = \frac{\hbar^2 k^2}{2m} \mp |J_{sd} \mathbf{m} + \alpha_R (\mathbf{k} \times \mathbf{z})| \approx \frac{\hbar^2 k^2}{2m} \mp \left( J_{sd} + \alpha_R k_y m_x + \frac{\alpha_R^2 (k^2 - k_y^2 m_x^2)}{2J_{sd}} \right)$$

$$E(m_x) = \int \frac{dk^2}{(2\pi)^2} (E_k^+ + E_k^-) \Rightarrow MCA = E(m_x = 1) - E(m_x = 0) \approx C \alpha_R^2$$

Shi et al. PRL '07

$$\boldsymbol{\mu} = i \frac{e}{2\hbar} \sum_{n\mathbf{k}} \langle \nabla_{\mathbf{k}} u_{n\mathbf{k}} | [\boldsymbol{\varepsilon}_n(\mathbf{k}) - \hat{H}_0(\mathbf{k})] \nabla_{\mathbf{k}} u_{n\mathbf{k}} \rangle \sim \alpha_R^2 M_z$$

Rashba model is able to capture the core physics of MCA.

MCA

OM

# Interfacial magnetocrystalline anisotropy

Kim, KJL, ... PRB 94, 184402 (2016)

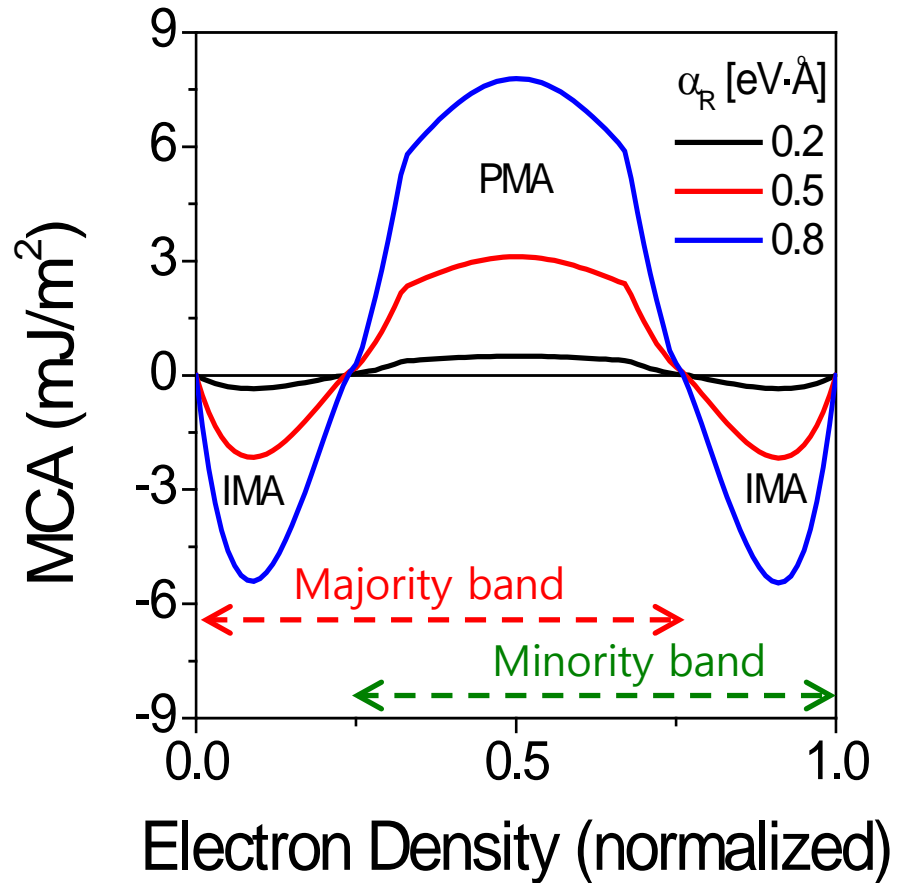
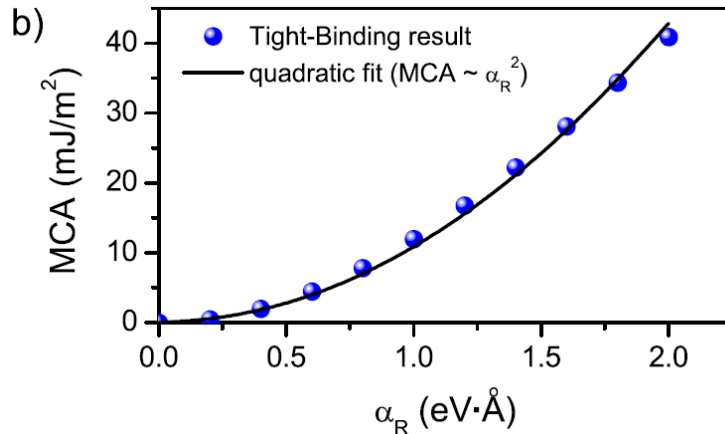
## Free electron model (parabolic band)

→ MCA vanishes once minority band is occupied.

### Tight-binding model

$$J_{sd} = 1 \text{ eV}, m_e = m_0$$

Square lattice



- RSOC → Interfacial MCA
- Band filling determines PMA / IMA

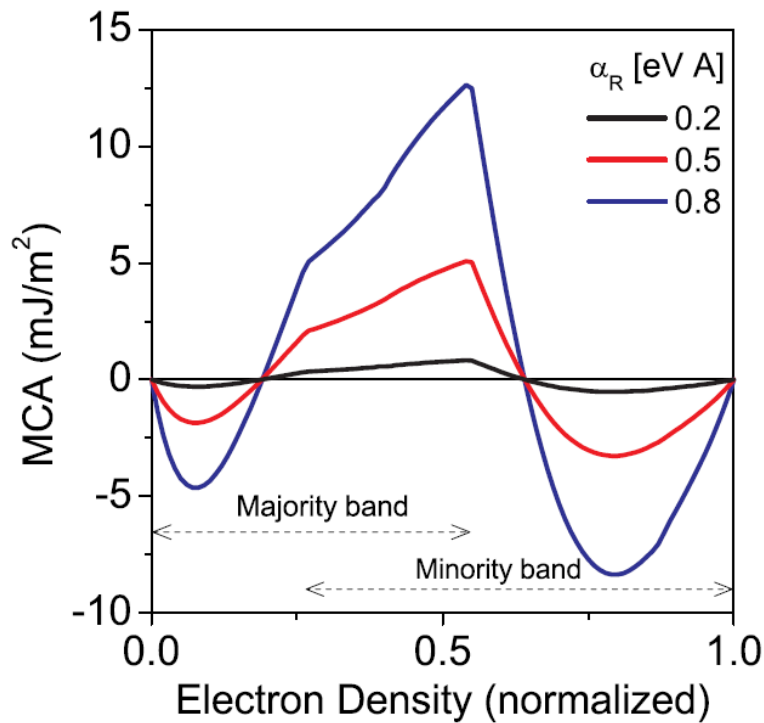


# Interfacial magnetocrystalline anisotropy

## Tight-binding model

$$J_{sd} = 1 \text{ eV}, m_e = m_0$$

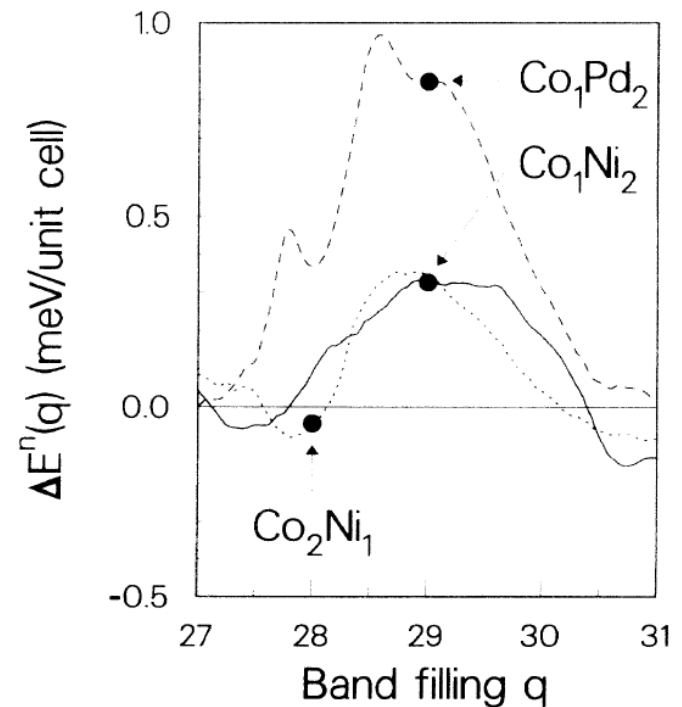
**Triangular lattice**



## First principles

Daalderop et al. PRL 68, 682 (1992).

**Co/Ni, Co/Pd multilayers (fcc 111)**



- Simple Rashba model captures the core effect of MCA

# Interfacial spin-orbit spin torques

“Magnetic interfaces (inversion asymmetry) + Spin-Orbit coupling”

Field-like torque

$$\mathbf{T}_f = \frac{2\alpha_R m_e}{\hbar^2} b_j \hat{\mathbf{y}} \times \hat{\mathbf{m}}$$

Damping-like torque (Slonczewski-like)

$$\mathbf{T}_d = -\frac{2\alpha_R m_e}{\hbar^2} \beta b_j \hat{\mathbf{m}} \times (\hat{\mathbf{y}} \times \hat{\mathbf{m}})$$

Adiabatic torque

$$\mathbf{T}_{\text{adia}} = b_j \partial_x \hat{\mathbf{m}}$$

Nonadiabatic torque

$$\mathbf{T}_{\text{non}} = -\beta b_j \hat{\mathbf{m}} \times \partial_x \hat{\mathbf{m}}$$

Adiabatic + field-like torque

$$\tilde{\mathbf{T}}_{\text{adia}} = b_j \tilde{\partial}_x \hat{\mathbf{m}}$$

Nonadiabatic + damping-like torque

$$\tilde{\mathbf{T}}_{\text{non}} = -\beta b_j \hat{\mathbf{m}} \times \tilde{\partial}_x \hat{\mathbf{m}}$$

$$\tilde{\partial}_x \hat{\mathbf{m}} \equiv \left( \partial_x + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \right) \hat{\mathbf{m}} = \partial_x \hat{\mathbf{m}} + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \hat{\mathbf{m}}$$

# Effects of Interfacial SOC (through 2D Rashba model Hamiltonian)

“Magnetic interfaces (inversion asymmetry) + Spin-Orbit coupling”

2D Rashba Hamiltonian



$$\begin{aligned}\mathcal{H} &= \mathcal{H}_{\text{kin}} + \mathcal{H}_R + \mathcal{H}_{\text{exc}} + \mathcal{H}_{\text{imp}} \\ &= \frac{\mathbf{p}^2}{2m_e} + \frac{\alpha_R}{\hbar} \boldsymbol{\sigma} \cdot (\mathbf{p} \times \hat{\mathbf{z}}) + J\boldsymbol{\sigma} \cdot \hat{\mathbf{m}} + \mathcal{H}_{\text{imp}},\end{aligned}$$

$$\mathcal{U}^\dagger \mathcal{H} \mathcal{U} = \mathcal{H}_{\text{kin}} + J\boldsymbol{\sigma} \cdot \hat{\mathbf{m}}' + \mathcal{H}'_{\text{imp}} + \mathcal{O}(\alpha_R^2),$$

where

$$\hat{\mathbf{m}}' = \mathcal{R}^{-1} \hat{\mathbf{m}}$$

K.-W. Kim et al. PRL 111,  
216601 (2013)



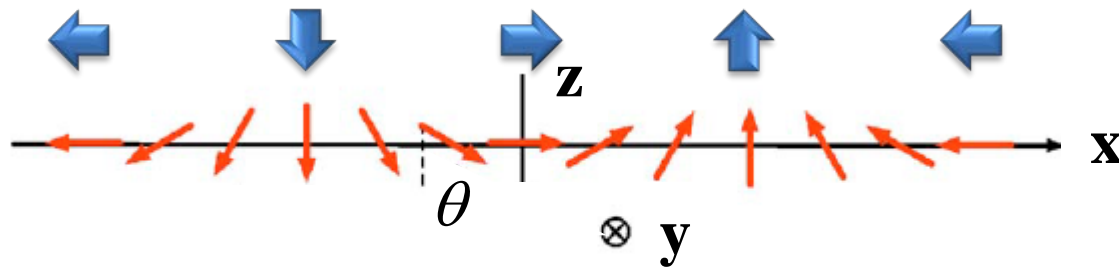
$$\tilde{\partial}_x \hat{\mathbf{m}} \equiv \left( \partial_x + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \right) \hat{\mathbf{m}} = \partial_x \hat{\mathbf{m}} + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \hat{\mathbf{m}}$$

# "Chiral" derivative

K.-W. Kim et al. PRL 111, 216601 (2013)

$$\tilde{\partial}_x \hat{\mathbf{m}} \equiv \left( \partial_x + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \right) \hat{\mathbf{m}} = \partial_x \hat{\mathbf{m}} + \frac{2\alpha_R m_e}{\hbar^2} \hat{\mathbf{y}} \times \hat{\mathbf{m}}$$

$$\tilde{\partial}_x \hat{\mathbf{m}} = 0$$



$$\frac{d\theta}{dx} = \frac{2\alpha_R m_e}{\hbar^2}$$

= precession rate of conduction electron spins due to RSOC

- No current-induced torque if magnetization precesses at the same rate as the conduction electrons would due to RSOC
- RSOC induces the chirality in the spin torques
- "Chiral" derivative captures RSOC effects

# Exchange “stiffness” energy

$$A \int dV \partial_x \hat{\mathbf{m}} \cdot \partial_x \hat{\mathbf{m}}$$

Exchange “stiffness” interaction mediated by conduction electrons

- Conduction electron mediation

$$A \int dV \partial_x \hat{\mathbf{m}} \cdot \partial_x \hat{\mathbf{m}}$$

↓ RSOC

$$A \int dV \tilde{\partial}_x \hat{\mathbf{m}} \cdot \tilde{\partial}_x \hat{\mathbf{m}}$$

Continuum version of interfacial  
Dzyaloshinskii-Moriya interaction (DMI)

$$= A \int dV \partial_x \hat{\mathbf{m}} \cdot \partial_x \hat{\mathbf{m}} + A \frac{4\alpha_R m_e}{\hbar^2} \int dV \hat{\mathbf{y}} \cdot \hat{\mathbf{m}} \times \partial_x \hat{\mathbf{m}}$$

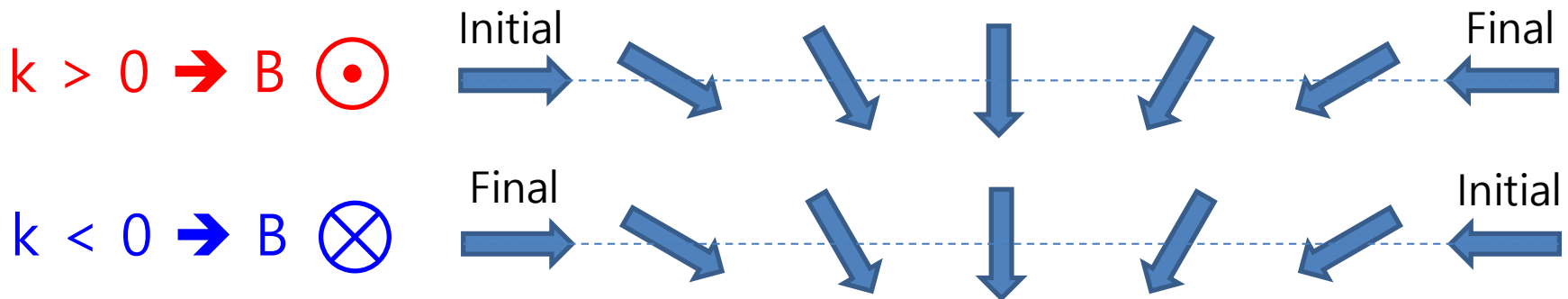
$$+ O(\alpha_R)^2$$

# A simple picture: why RSOC $\Leftrightarrow$ DMI

- DMI = Current-**INDEPENDENT** magnetic energy

→ Contributions from spins with  $+k$  + Cont. from spins with  $-k \neq 0$

- RSOC → effective B field in  $\mathbf{k} \times$  (interface normal)



→ Conduction electron spins are chiral

→ + s-d exchange

→ Localized electron spins ( $\mathbf{m}$ ) tend to be chiral

# Spin motive force (SMF)

$$\mathbf{E}_{\pm} = \pm \sum_{i=x,y} \hat{\mathbf{x}}_i \frac{\hbar}{2e} \partial_t \hat{\mathbf{m}} \times \partial_i \hat{\mathbf{m}} \cdot \hat{\mathbf{m}}$$

Berger, PRB 1986  
 Volovik, JPC 1987  
 Barnes & Maekawa, PRL  
 2007

With RSOC

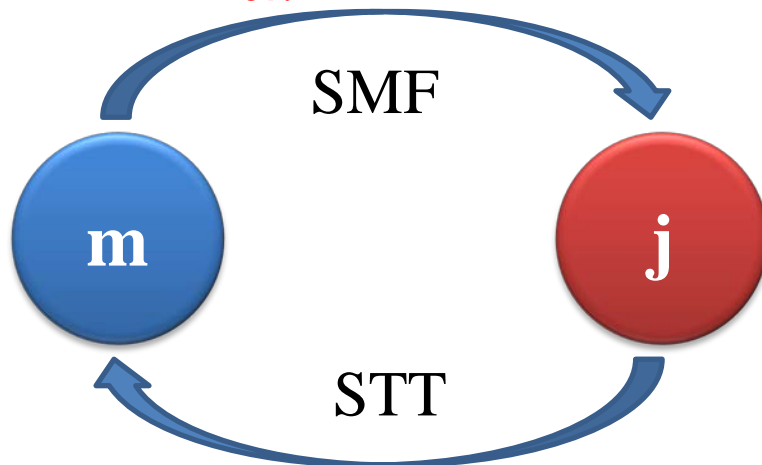
$$\tilde{\mathbf{E}}_{\pm} = \pm \sum_{i=x,y} \hat{\mathbf{x}}_i \frac{\hbar}{2e} \partial_t \hat{\mathbf{m}} \times \tilde{\partial}_i \hat{\mathbf{m}} \cdot \hat{\mathbf{m}}$$

$$= \pm \sum_{i=x,y} \hat{\mathbf{x}}_i \frac{\hbar}{2e} \partial_t \hat{\mathbf{m}} \times \partial_i \hat{\mathbf{m}} \cdot \hat{\mathbf{m}} \pm \sum_{i=x,y} \hat{\mathbf{x}}_i \frac{\hbar}{2e} \partial_t \hat{\mathbf{m}} \times \left[ \frac{2\alpha_R m_e}{\hbar^2} (\hat{\mathbf{z}} \times \hat{\mathbf{x}}_i) \times \hat{\mathbf{m}} \right] \cdot \hat{\mathbf{m}}$$

$$= \mathbf{E}_{\pm} \pm \frac{\alpha_R m_e}{e\hbar} \hat{\mathbf{z}} \times \partial_t \hat{\mathbf{m}}$$

Kim, Moon, KJL, HWL, PRL 2012

Foros et al. PRB '08  
 Tserkovnyak & Wong, PRB '09  
 Zhang & Zhang, PRL 2009



→ Feedback-induced modification  
 of Landau-Lifshitz-Gilbert eq.

# Feedback effect on LLG equation (1)

- Feedback-induced damping torque

$$\mathbf{T}_{\text{feedback}} = \mathbf{m} \times \delta \tilde{\alpha}_G \cdot \frac{\partial \mathbf{m}}{\partial t}$$

$$(\delta \tilde{\alpha}_G)_{ij} = \eta \sum_k \left( X_{ki} + \frac{2\alpha_R m_e}{\hbar} \varepsilon_{3ki} \right) \left( X_{kj} + \frac{2\alpha_R m_e}{\hbar} \varepsilon_{3kj} \right), \quad X_{ki} = \left( \mathbf{m} \times \frac{\partial \mathbf{m}}{\partial x_k} \right)_i, \quad \eta = \frac{\mu_B \hbar \sigma_c}{2e^2 M_s}$$

Zhang & Zhang, PRL '09

Kim, Moon, KJL, HWL, PRL 2012

## Single domain

$$\tilde{\alpha} = \begin{pmatrix} \alpha_0 + C\alpha_R^2 & 0 & 0 \\ 0 & \alpha_0 + C\alpha_R^2 & 0 \\ 0 & 0 & \alpha_0 \end{pmatrix}$$

## Domain wall

$$\hat{\mathbf{m}} = \left( \cos \phi \operatorname{sech} \left( \frac{x}{\lambda} \right), \sin \phi \operatorname{sech} \left( \frac{x}{\lambda} \right), \tanh \left( \frac{x}{\lambda} \right) \right)$$

$$\tilde{\alpha}_{22} \approx \alpha_0 - \frac{C}{\lambda} \cos \phi \operatorname{sech} \left( \frac{x}{\lambda} \right) \alpha_R + O(\alpha_R^2)$$

→ Anisotropic enhanced Gilbert damping

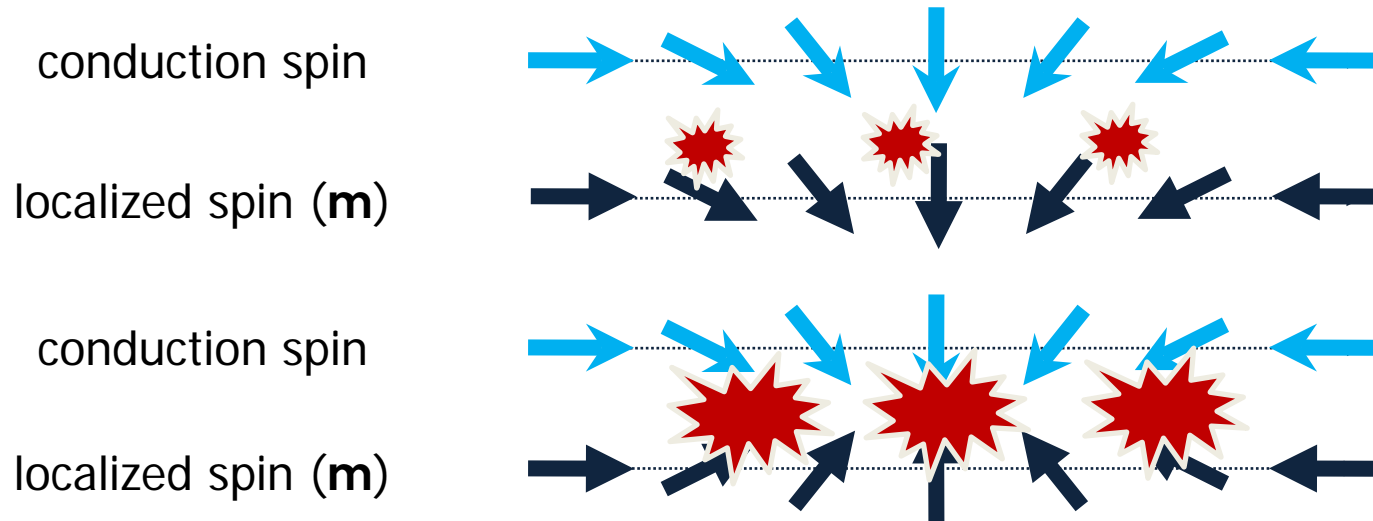
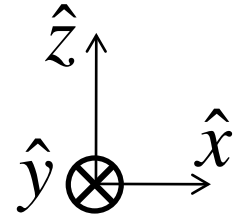
→ **Magnetic texture-dependent Chiral damping**



# Chiral damping

- Interfacial Rashba effect

Effective magnetic field  $\mathbf{B}_R \propto \alpha_R (\mathbf{k} \times \hat{\mathbf{z}})$



: Non-compensated chirality of conduction electron spin

→ Chirality of localized electron spin due to s-d exchange coupling

(Dzyaroshinskii-Moriya interaction)

: More frequent scattering → **chiral damping**

# Spin-dependent magnetic field

$$\mathbf{B}_{\pm} = \mp \hat{\mathbf{z}} \frac{\hbar}{2e} \left( \partial_x \hat{\mathbf{m}} \times \partial_y \hat{\mathbf{m}} \right) \cdot \hat{\mathbf{m}}$$

Volovik, JPC 1987

With RSOC

$$\tilde{\mathbf{B}}_{\pm} = \mp \hat{\mathbf{z}} \frac{\hbar}{2e} \left( \tilde{\partial}_x \hat{\mathbf{m}} \times \tilde{\partial}_y \hat{\mathbf{m}} \right) \cdot \hat{\mathbf{m}}$$

$$= \mp \hat{\mathbf{z}} \frac{\hbar}{2e} \left( \partial_x \hat{\mathbf{m}} \times \partial_y \hat{\mathbf{m}} \right) \cdot \hat{\mathbf{m}} \pm \frac{\alpha_R m_e}{e \hbar} \nabla \times (\hat{\mathbf{z}} \times \hat{\mathbf{m}}) \pm \frac{2\alpha_R^2 m_e^2}{e \hbar^3} m_z \hat{\mathbf{z}}$$

RSOC contribution to  
anomalous Hall effect  
(Bijl-Duine PRB '12)

**Topological Hall Effect**

**(2<sup>nd</sup> Rashba term)/(1<sup>st</sup> Conv. Term) ~ 1**

**Spin spirals can be detected**

SdME

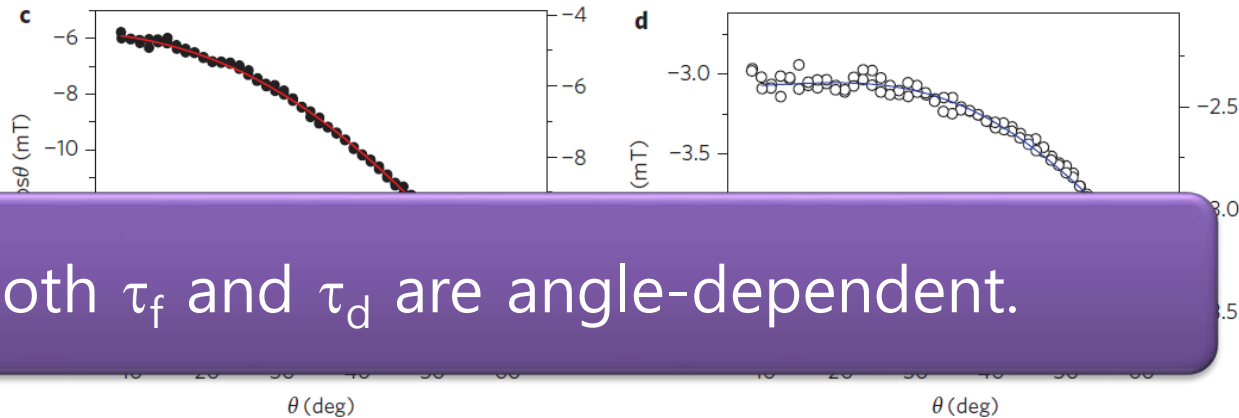
**$\beta$  becomes tensor,  
anisotropic, and  
texture-dependent**

SII

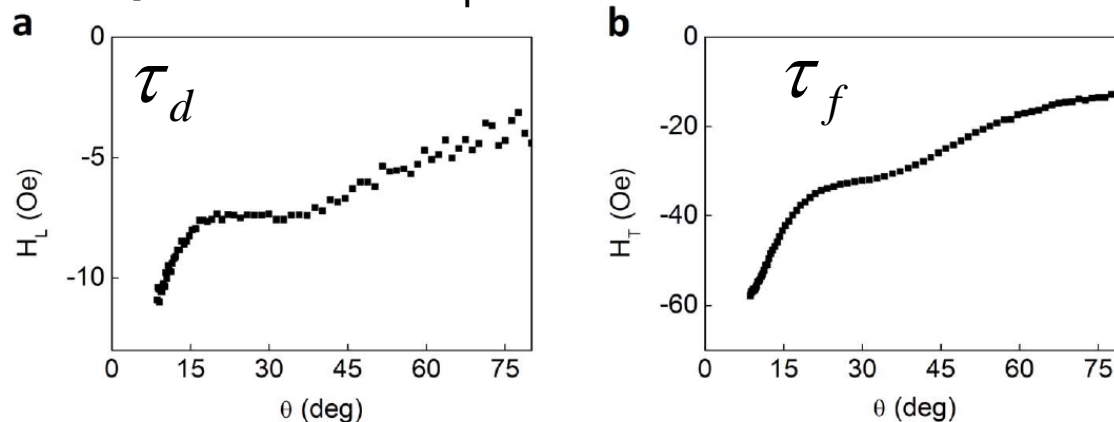
# Angular dependence of SOTs: Previous Experiments

$$\mathbf{SOT} = \tau_f \hat{\mathbf{m}} \times \hat{\mathbf{y}} + \tau_d \hat{\mathbf{m}} \times (\hat{\mathbf{m}} \times \hat{\mathbf{y}})$$

Experiment: Garello et al. Nat. Nanotech. 2013



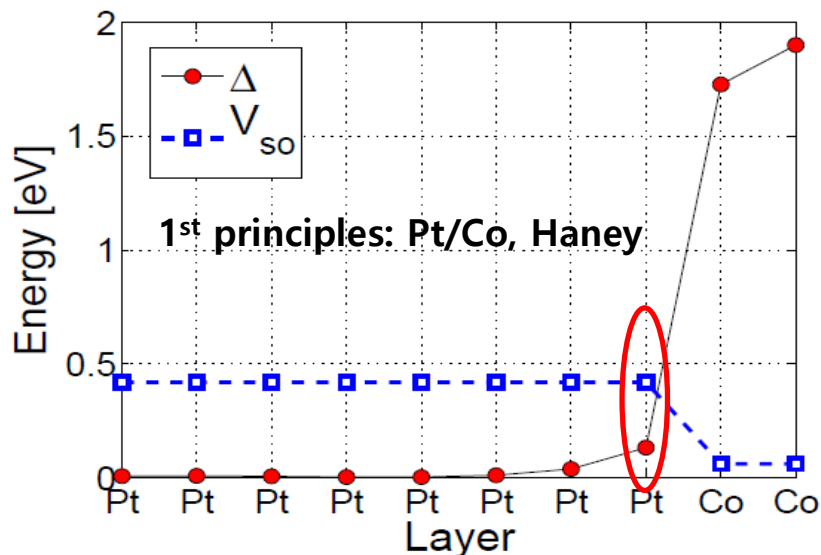
Experiment: Qiu et al. Sci. Rep. 2013



# Angular dependence of SOTs: Previous Theories

$$\mathbf{SOT} = \tau_f \hat{\mathbf{m}} \times \hat{\mathbf{y}} + \tau_d \hat{\mathbf{m}} \times (\hat{\mathbf{m}} \times \hat{\mathbf{y}})$$

- Bulk SOC in HM (SHE: Haney et al. PRB '13)
  - No angular dependence (1<sup>st</sup> order of SH angle)
- Interfacial SOC (Rashba: Pauyac et al. APL '13)
  - Weak Rashba regimes: both are almost constant
  - Strong Rashba regimes:  $\tau_f = \text{constant}$ ,  $\tau_d = \text{angle-dependent}$



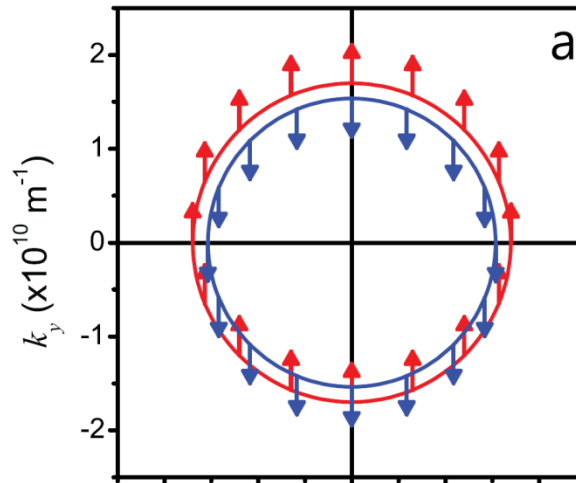
**Berry phase contribution  
to  $\tau_d$  (Kurebayashi et al.  
Nat. Nano. '14)**

# Fermi surface distortion due to Rashba SOC

**Ferromagnet**

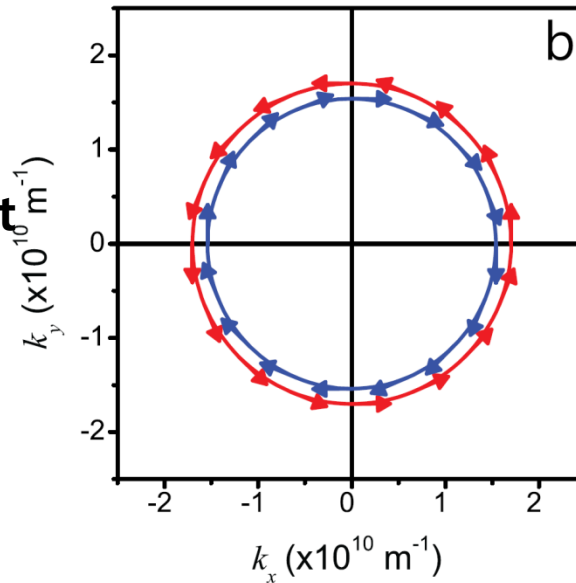
$$\alpha_R = 0 \text{ \& } J_{sd} \neq 0$$

$$\mathbf{M} = (0, 1, 0)$$



**Rashba non-magnet**

$$\alpha_R \neq 0 \text{ \& } J_{sd} = 0$$

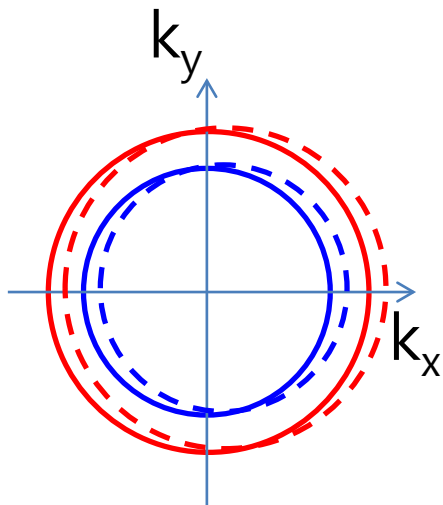


# SOT: Fermi surface contribution $\rightarrow \tau_f$

E-field

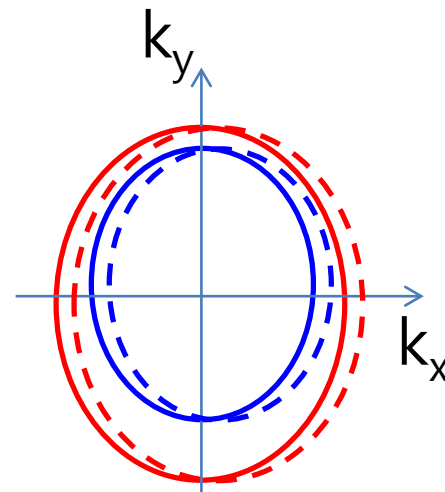


$$\mathbf{M} = M_z$$



Circle & Concentric

$$\mathbf{M} = M_x$$



Ellipse & Non-concentric

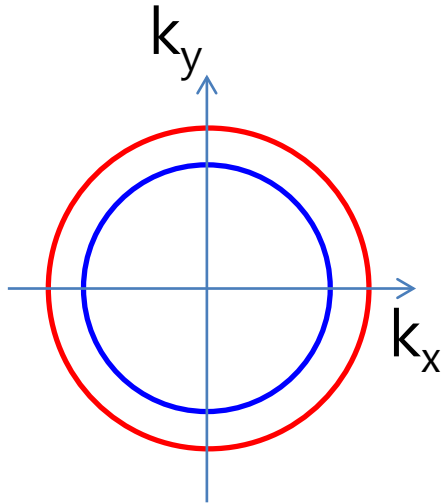
$$\tau_f(M_z) \neq \tau_f(M_x)$$

# SOT: Fermi sea contribution (Berry phase) $\rightarrow \tau_d$

E-field



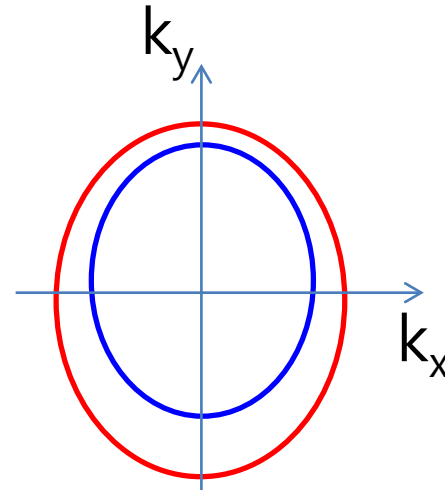
$$\mathbf{M} = M_z$$



Circle & Concentric

$$s_{\mathbf{k}(2)}^{\pm} = \mp \frac{\hbar}{2} \alpha_R e E \left( \frac{J_{sd} m_z}{2\epsilon_{\mathbf{k}}^3}, 0, -\frac{\alpha_R k_y + J_{sd} m_x}{2\epsilon_{\mathbf{k}}^3} \right)$$

$$\mathbf{M} = M_x$$

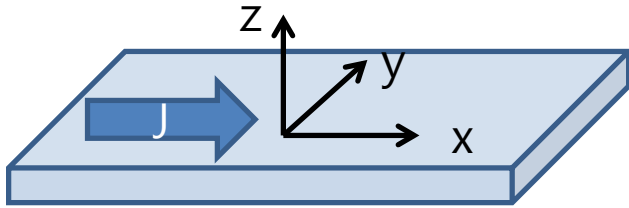


Ellipse & Non-concentric

$$\tau_d(\mathbf{M}_z) \neq \tau_d(\mathbf{M}_x)$$

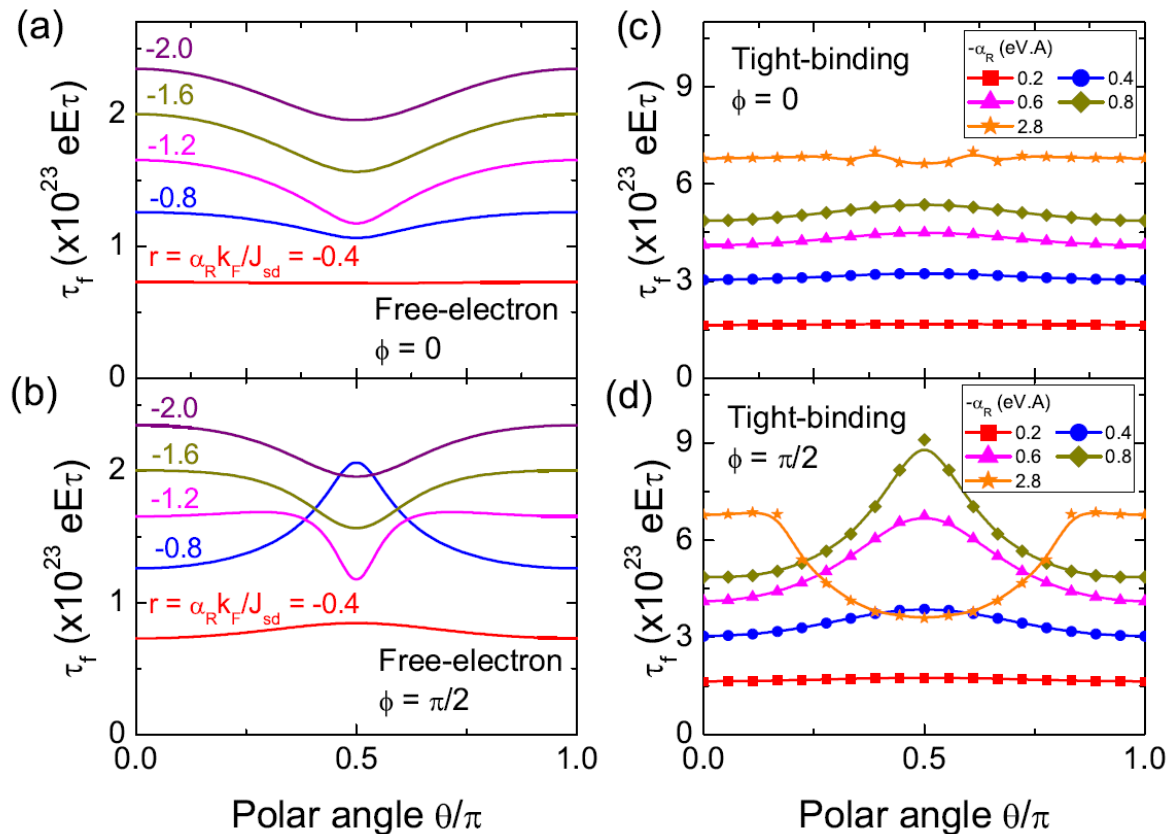
# Field-like torque ( $\tau_f$ ): Fermi surface contribution

Lee et al. PRB 91, 144401 (2015)



$$\hat{\mathbf{m}} = (\cos \phi \sin \theta, \sin \phi \sin \theta, \cos \theta)$$

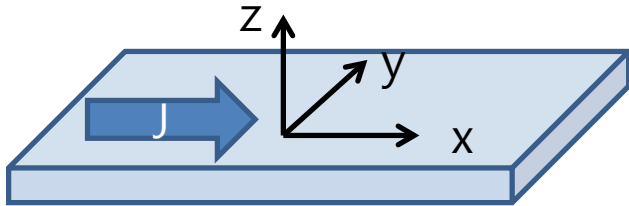
$$E_F = 10 \text{ eV}, J_{sd} = 1 \text{ eV}, m^* = m_0$$



Strong angular dependence near  $\alpha_R k_F / J_{sd} = 1 \rightarrow$  FS distortion

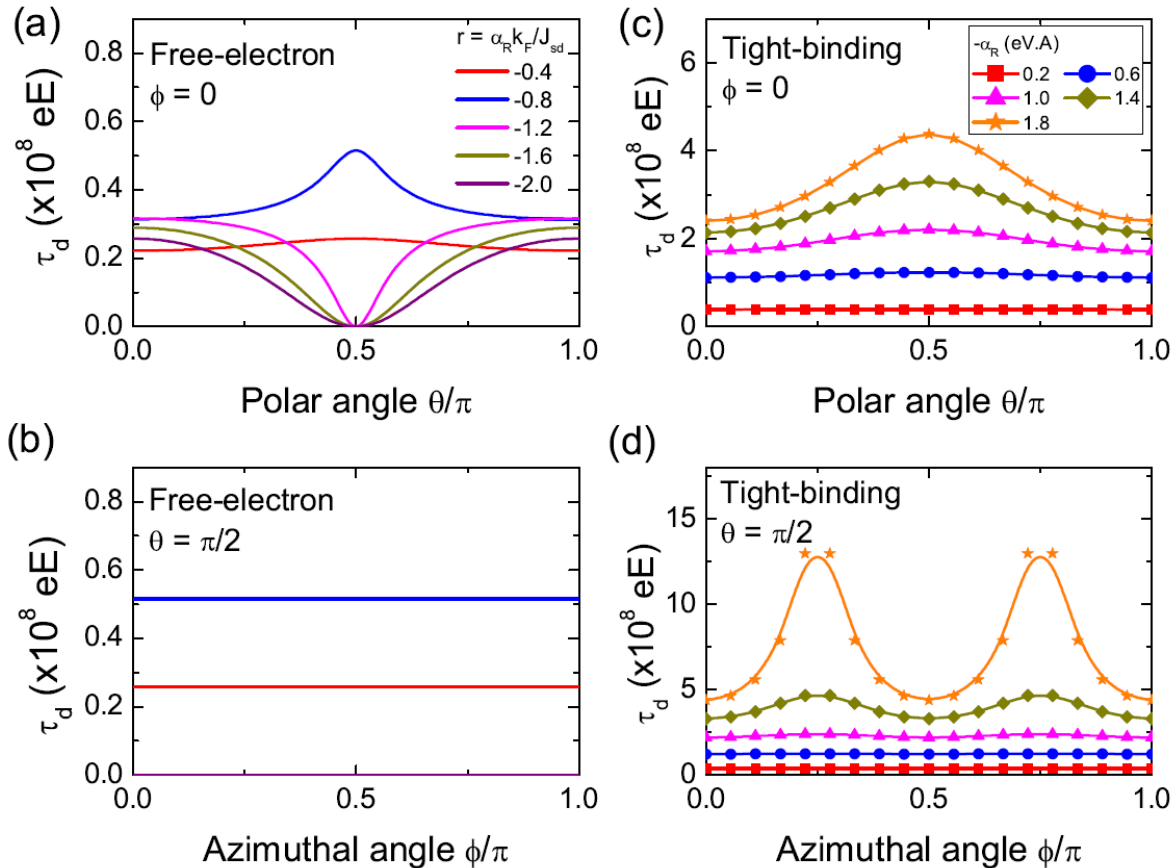


# Damping-like torque ( $\tau_d$ ): Fermi sea contribution



$$\hat{\mathbf{m}} = (\cos \phi \sin \theta, \sin \phi \sin \theta, \cos \theta)$$

$$E_F = 10 \text{ eV}, J_{sd} = 1 \text{ eV}, m^* = m_0$$



Strong angular dependence near  $\alpha_R k_F / J_{sd} =$  or  $> 1$

# Angle-dependent SOT: Switching and DW motion

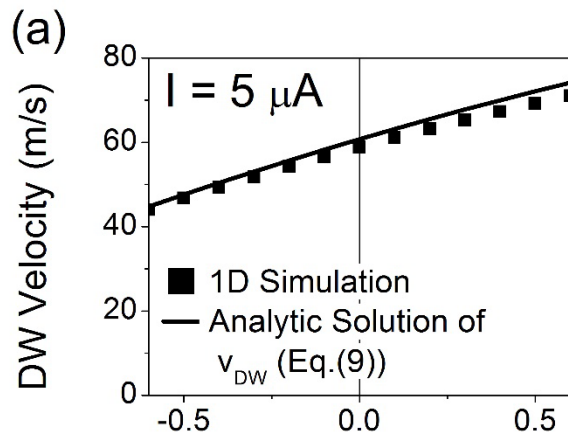
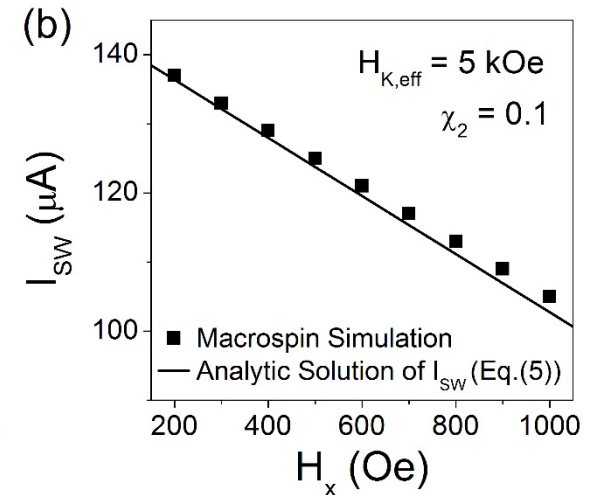
Seo-Won Lee and KJL, JKPS '15

$$\frac{\partial \hat{\mathbf{m}}}{\partial t} = -\gamma \hat{\mathbf{m}} \times \mathbf{H}_{\text{eff}} + \alpha \hat{\mathbf{m}} \times \frac{\partial \hat{\mathbf{m}}}{\partial t} + \gamma \tau_{d0} \hat{\mathbf{m}} \times \left[ (\hat{\mathbf{m}} \times \hat{\mathbf{y}}) + \hat{\mathbf{z}} (\hat{\mathbf{m}} \cdot \hat{\mathbf{x}}) (\chi_2 + \chi_4 (\hat{\mathbf{m}} \times \hat{\mathbf{z}})^2) \right]$$

Angle-dependent part

Single domain switching

$$\tau_{d0}^{sw} = H_{K, \text{eff}} \left( \frac{\sqrt{\Gamma - h^4 + 20h^2}}{4\sqrt{2}} + \frac{h^6 + (h^5 - 4h^3 + 12h)\sqrt{8 + h^2} + 12h^2 - 16}{16\sqrt{2}\sqrt{\Gamma - h^4 + 20h^2}} \chi_2 \right),$$



DW speed

$$v_{DW} = \gamma \frac{\pi}{2} \frac{\lambda D_0 \tau_{d0} \left( 1 + \frac{\chi_2}{2} + \frac{3}{8} \chi_4 \right)}{\sqrt{D_0^2 \alpha^2 + M_S^2 \tau_{d0}^2 \left( 1 + \frac{\chi_2}{2} + \frac{3}{8} \chi_4 \right)^2} \lambda^2}$$

(c)

$\chi_2$

# Summary

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1. Crucial role of SOC in magnetic properties and spin transport
2. Understanding of these SOC-related phenomena based on orbital moment
3. Rashbaness is always preserved for inversion symmetry broken systems
4. Orbital engineering is key to make SOC phenomena useful